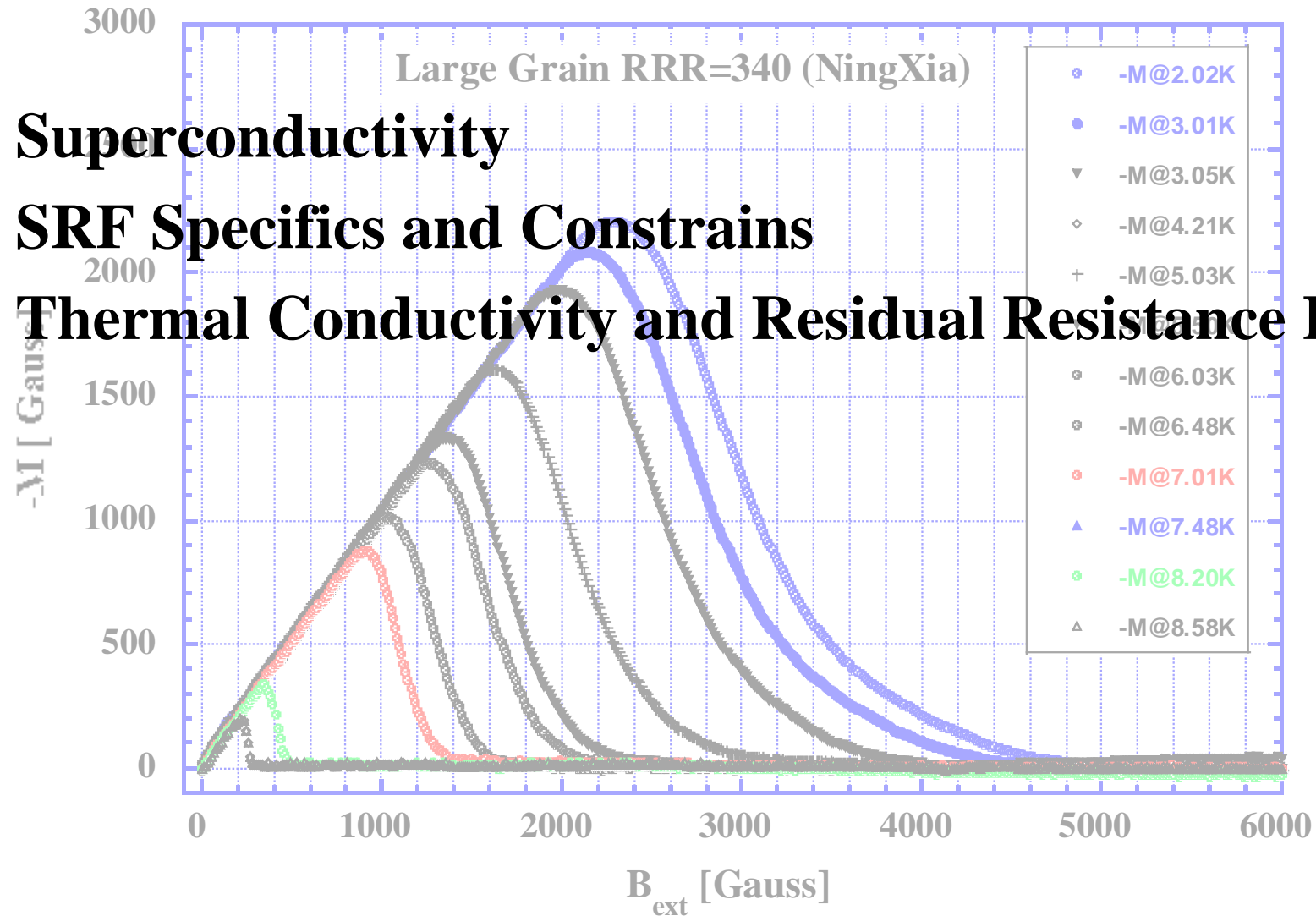


1. Superconductivity Basics for SRF Cavity

1.1 Superconductivity

1.2 SRF Specifics and Constrains

1.3 Thermal Conductivity and Residual Resistance Ratio



Superconductivity

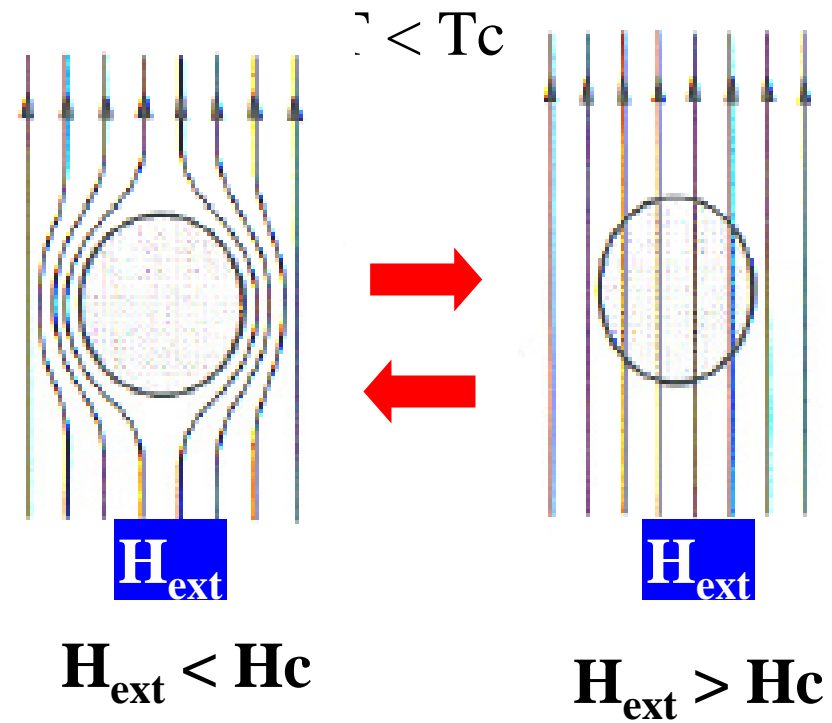
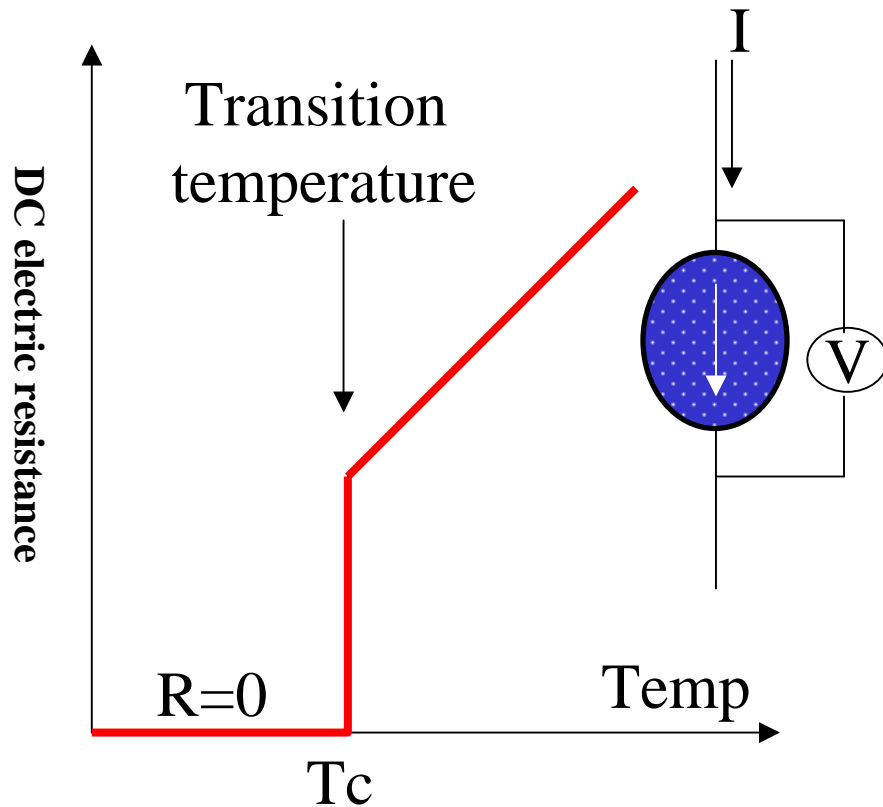
1911 by K. Onnes

Zero resistance @ T_c

1933 by Meissner and Ochsenfeld (experiment)
1935 Phenomenological theory by F. and H. London

Perfect diamagnetism $< H_c$

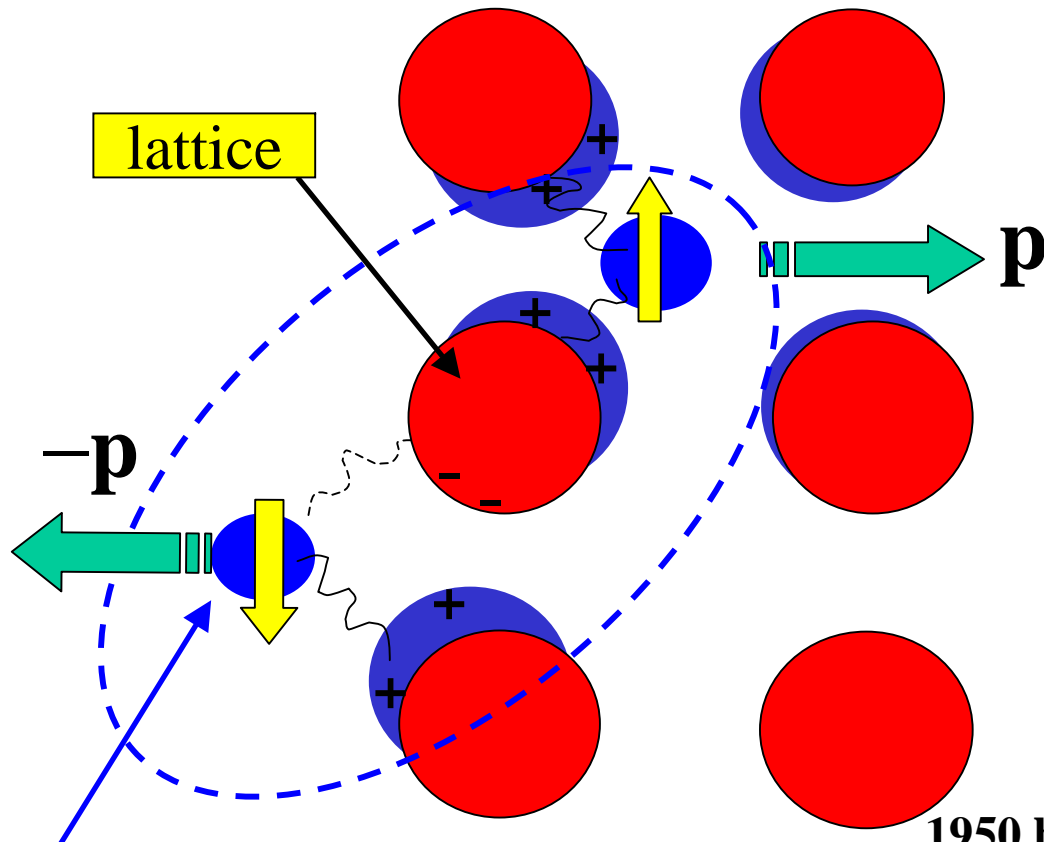
Meissner effect



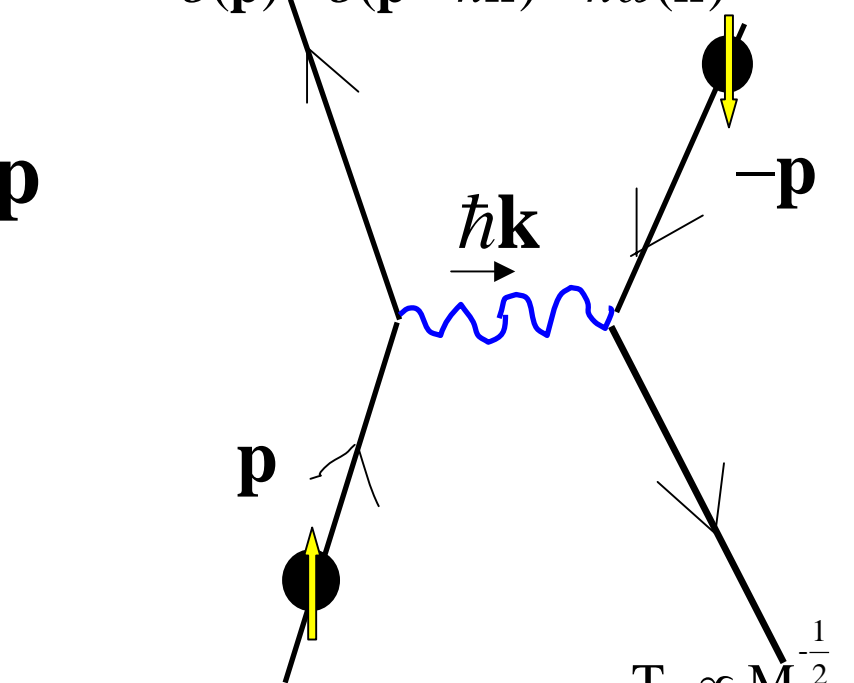
Microscopic Theory

Two electrons having opposite spin and momentum get an attractive interaction through lattice/electron interaction.

Attractive interaction through electron-lattice interaction $V = \frac{|V_{\mathbf{p}-\hbar\mathbf{k},\mathbf{p}}|^2}{\varepsilon(\mathbf{p}) - \varepsilon(\mathbf{p} - \hbar\mathbf{k}) - \hbar\omega(\mathbf{k})}$



Electron with down spin



Isotope effect of Tc
1950 by Reynolds and Maxwell

BCS theory
1957 by Bardeen, Cooper, and Schrieffer

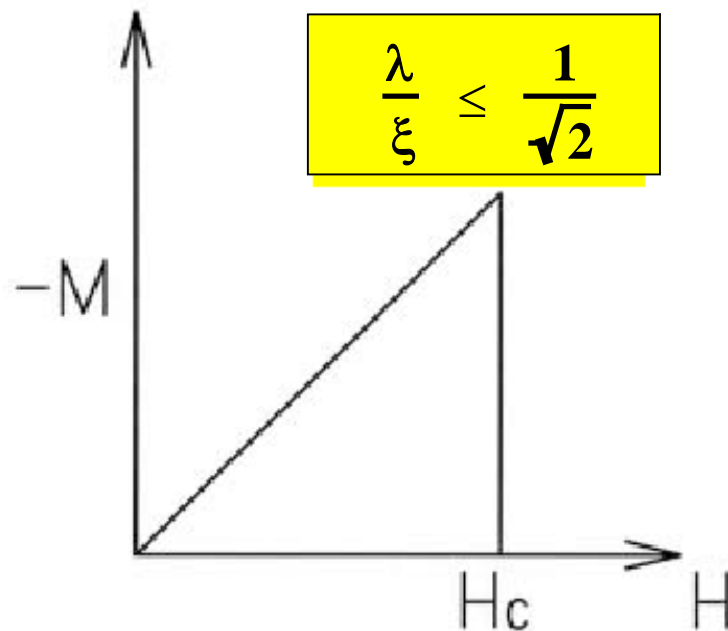
$$T_C \propto M^{-\frac{1}{2}},$$

$$H_C \propto M^{-\frac{1}{2}}$$

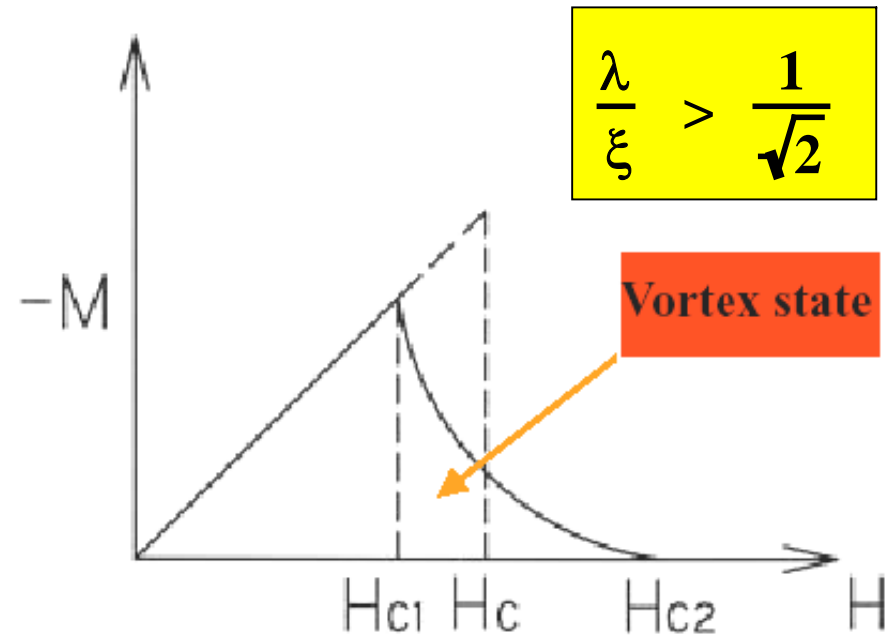
Two Types of Superconductor

1937 by Schubnikov (experiment), 1957 Abrikosov (theory)

Type-I



Type-II



$$G_n - G_s = \frac{1}{2} \mu H_c^2 \equiv \int_0^{H_{c2}} M dH$$

Vortex state

Flux quantization, 1961 by Deaver and Fairbank

Observed by iron powder

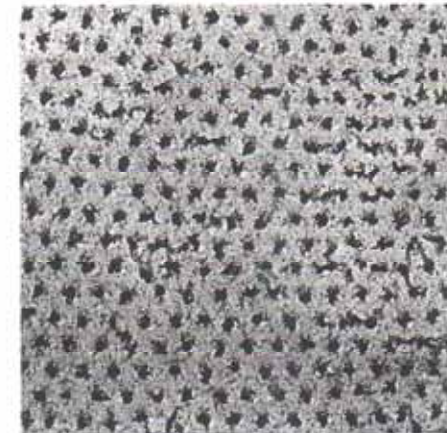
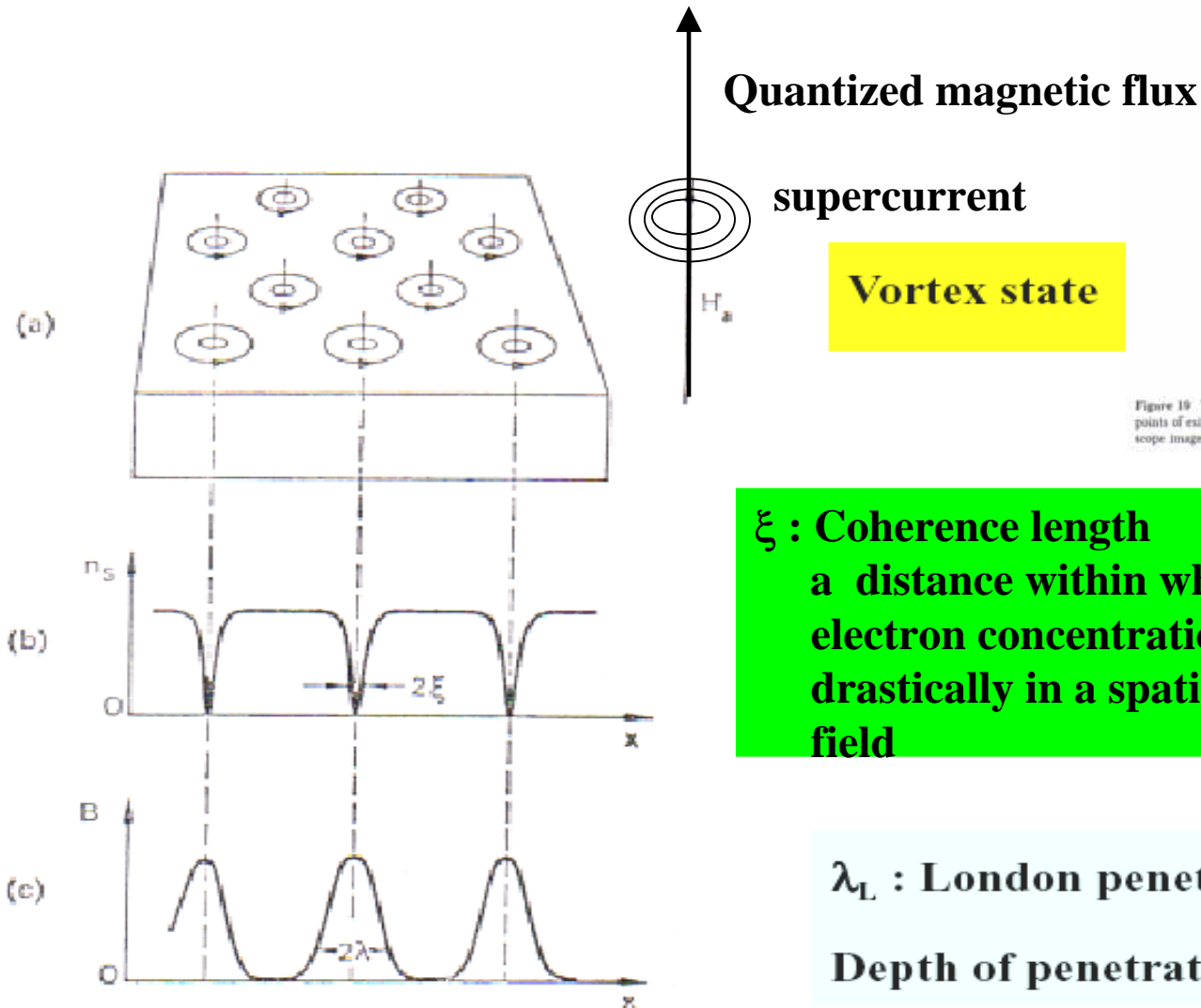


Figure 19. Triangular lattice of fluxoids through top surface of a superconducting cylinder. The points of exit of the flux lines are decorated with fine ferromagnetic particles. The electron microscope image is at a magnification of 8300, by U. Esmann and H. Trüble.

ξ : Coherence length

a distance within which the superconducting electron concentration cannot change drastically in a spatially-varying magnetic field

λ_L : London penetration depth

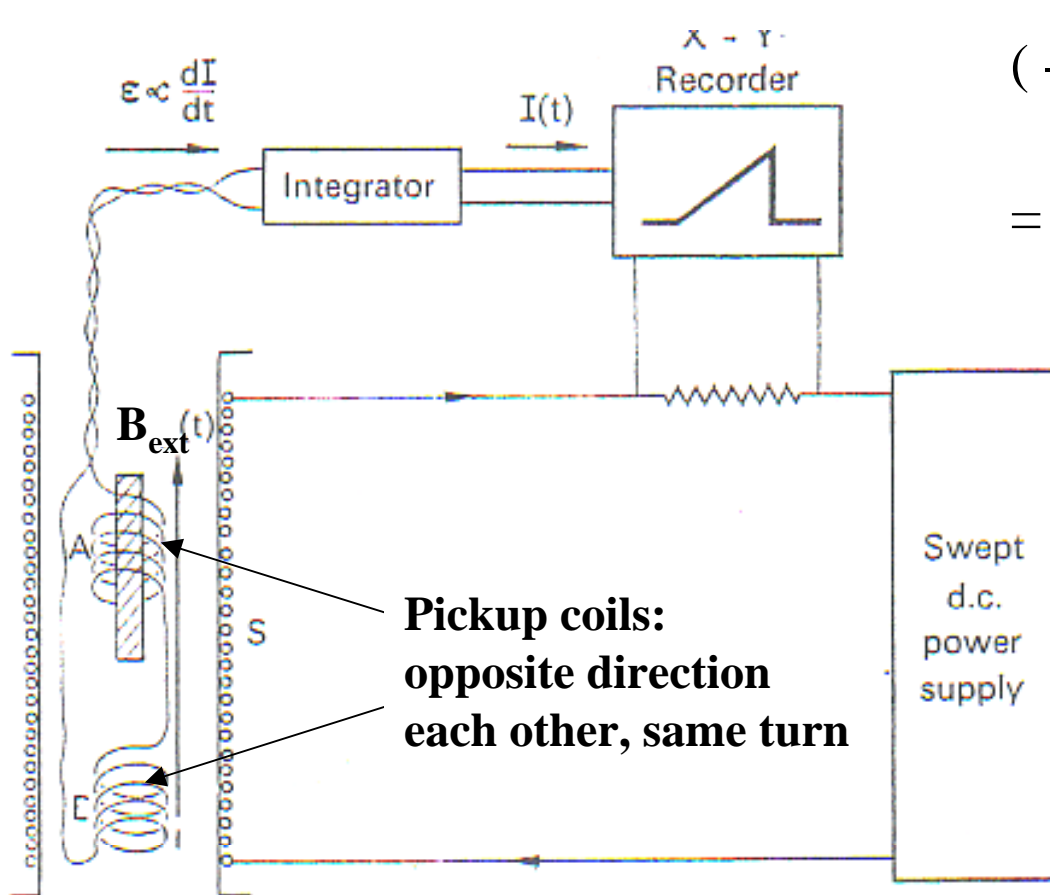
Depth of penetration of the magnetic field

Critical magnetic field measurement

$$V = V_A + V_B = -\frac{d}{dt}\Phi_A + \frac{d}{dt}\Phi_B$$

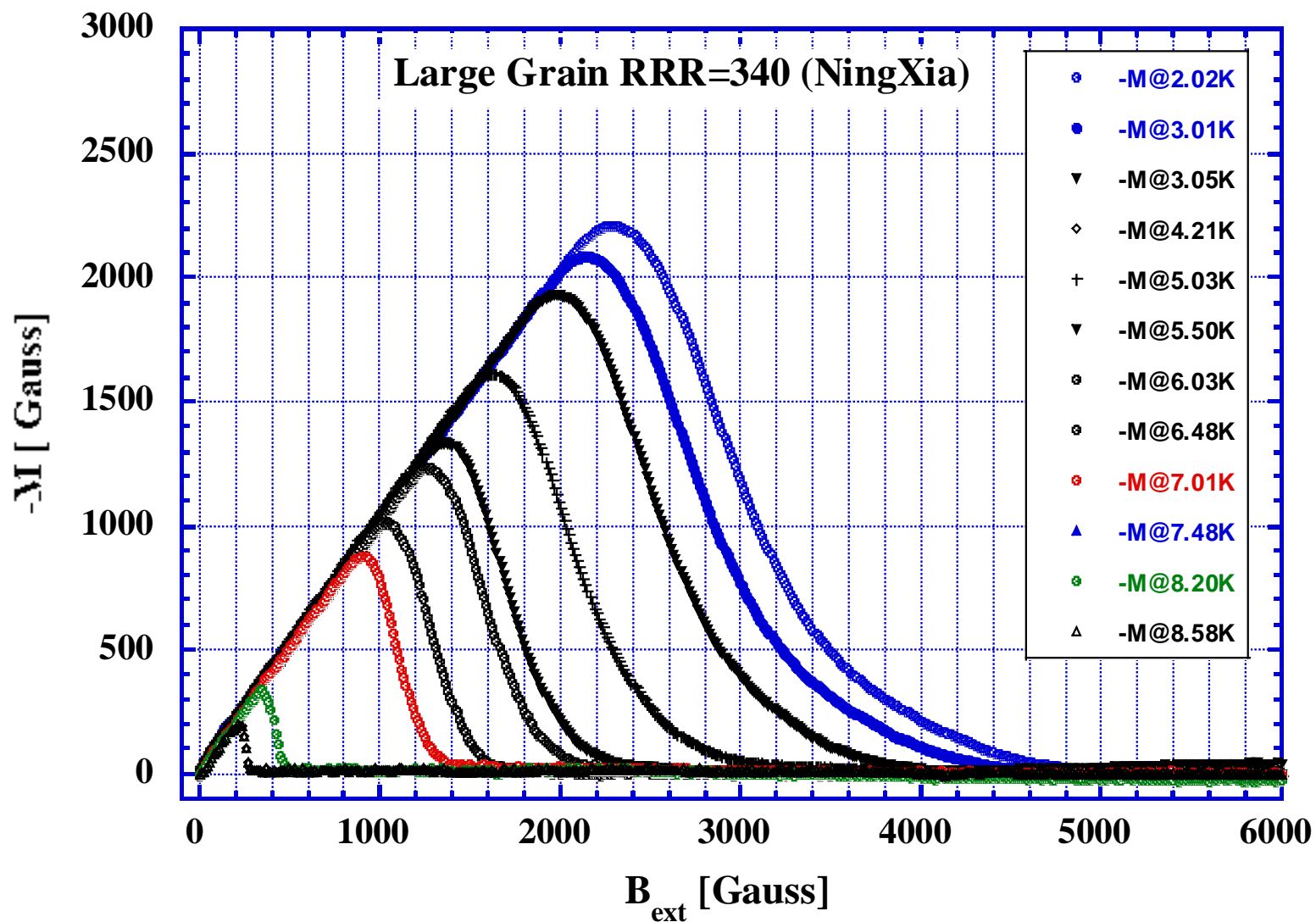
$$\left(-nS_0\mu\frac{d}{dt}B_{ext} + \frac{d}{dt}M\right) + nS_0\mu\frac{d}{dt}B_{ext}$$

$$= \frac{d}{dt}M$$



$$M = \int_0^t V dt$$

Example of demagnetization curve on Niobium (NingXia, Large Grain RRR=340)



Abrikosov's Theory for Type-II

Perturbation theory $T \sim T_c$

$$H_c = \frac{\kappa}{\lambda^2} \frac{\hbar c}{\sqrt{2e}^*} = \frac{\kappa}{\lambda^2} \frac{(hc / 2e)}{2\pi\sqrt{2}} = \frac{\phi_0}{2\pi\sqrt{2}\lambda\xi}$$

$$H_{c2} = \sqrt{2} \frac{\lambda}{\xi} \frac{\phi_0}{2\pi\sqrt{2}\lambda\xi} = \frac{\phi_0}{2\pi\xi^2}$$

$$H_{c1} = \frac{\phi_0}{4\pi\lambda^2} \ln\left(\frac{\lambda}{\xi} + 0.08\right)$$

$$\begin{aligned} \phi_0 &= hc / 2e = 2.0678 \times 10^{-7} \text{ Gauss} \cdot \text{cm}^2 \\ &= 2.0678 \times 10^{-15} \text{ T} \cdot \text{m}^2 \end{aligned}$$

$$H_C(T) = H_C(0) \left[1 - (T/T_C)^2 \right]$$

$$\lambda(T) = \frac{\lambda(0)}{\sqrt{1 - (T/T_C)^4}}$$

Exercise I.

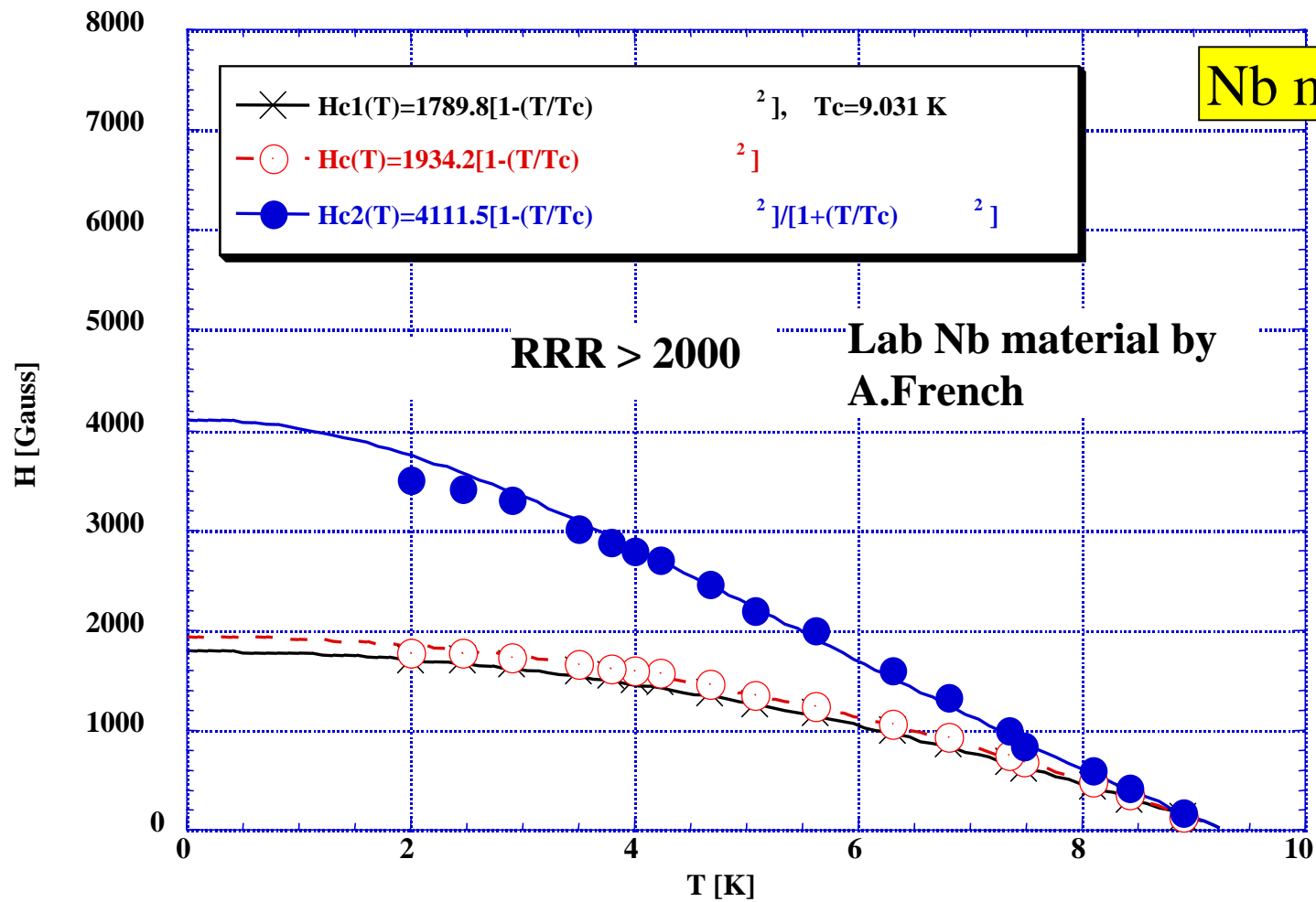
Show the formulas for ξ , λ by H_c, H_{c2} .

Get the T-dependences for ξ , H_{c2} , κ , H_C^{RF} .

Expand for all T range (assumption)

$$\xi(T) = \xi(0) \cdot \sqrt{\frac{1 + (T/T_C)^2}{1 - (T/T_C)^2}} \quad \kappa(T) = \frac{\kappa(0)}{1 + (T/T_C)^2}$$

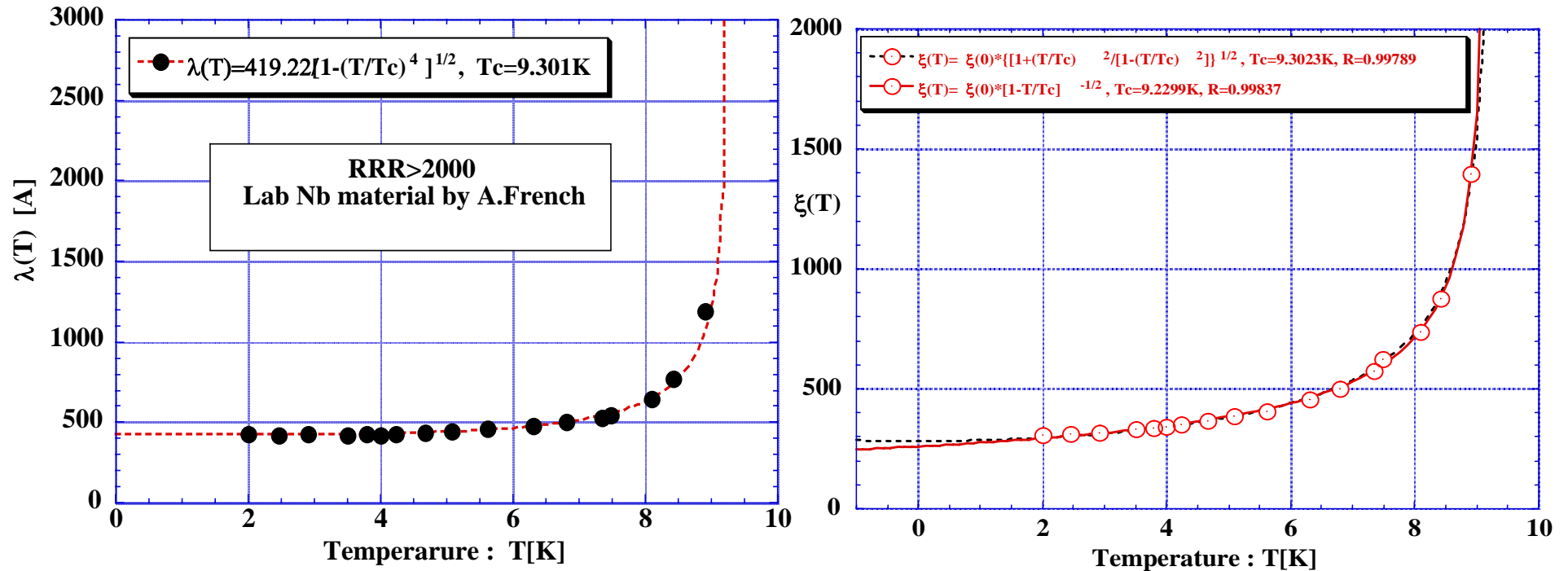
T-dependence of H_{C1} , H_C , H_{C2}



$$H_c(T) = H_c(0) \cdot \left[1 - \left(\frac{T}{T_c} \right)^2 \right]$$

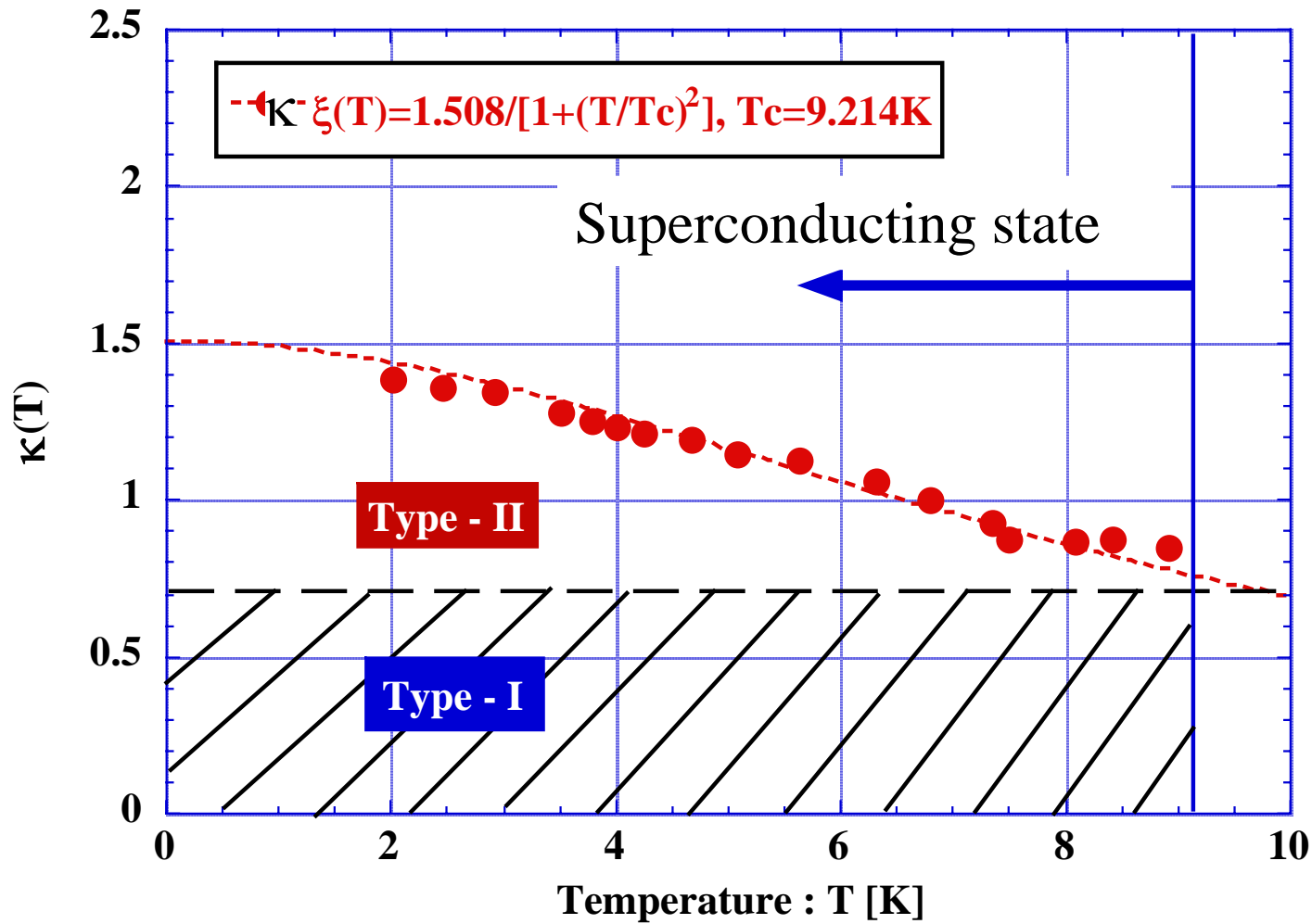
T-dependence of λ and ξ

Lab material, RRR>2000



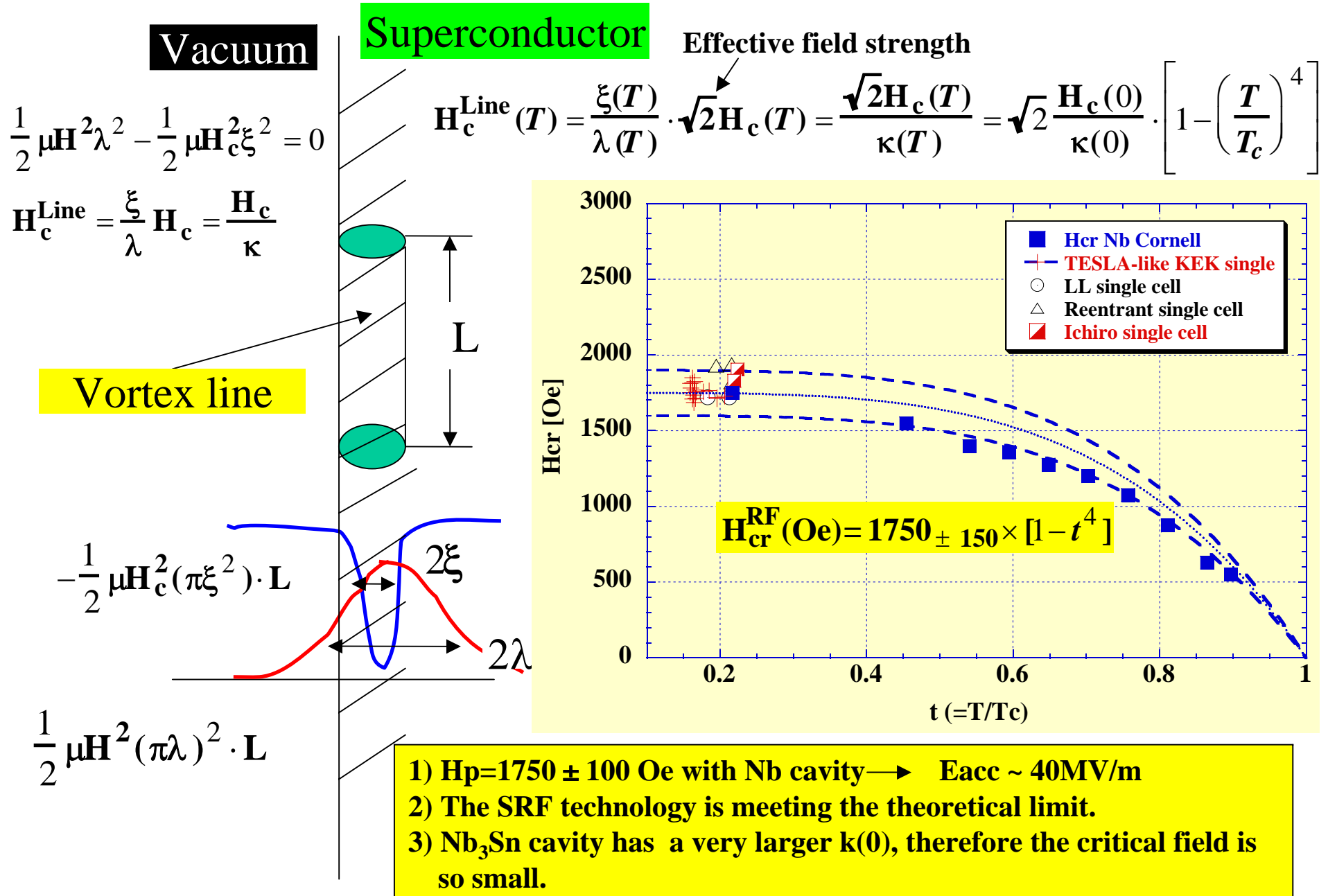
$$\lambda(T) = \frac{\lambda(0)}{\sqrt{1 - (T/T_c)^4}}, \quad \xi(T) = \xi(0) \cdot \sqrt{\frac{1 + (T/T_c)^2}{1 - (T/T_c)^2}}$$

T-dependence of κ with Lab material



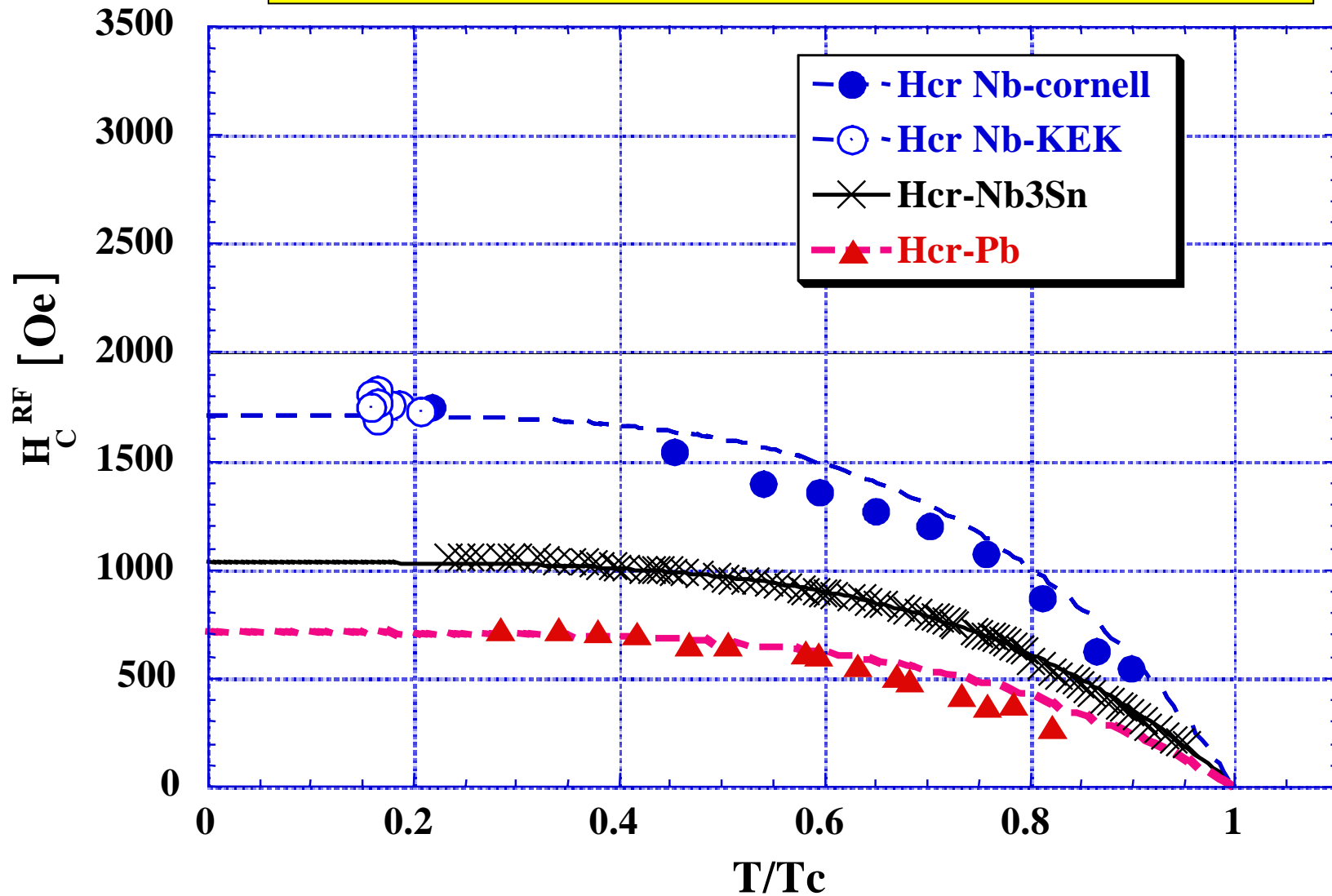
$$\kappa(T) = \frac{\kappa(0)}{1 + (T/T_c)^2}$$

Attempt for RF Field limitation model



Checking of the model for other materials

The model looks good for the type-II material cavity !



What material is best for SRF cavity?

Material point of view:

- Smaller heat loading for refrigerator → **Higher T_c**

- High gradient

$H_{RF} > H_c^{RF}$, then normal conducting

$$H_c^{RF} = \sqrt{2} \cdot \frac{H_c}{\kappa}, \quad \kappa : G - L \text{ parameter}$$

This is very much different from superconducting magnet

The material with higher H_c and smaller κ -value

If H_c is high enough, Type-I material is better because of the smaller κ -value.

- Good formability

Materials	T_c [K]	H_c , [Gauss]	H_{c1}	Type	Fabrication
Pb	7.2	803		I	Electroplating
Nb	9.25	1900,	1700	II	Deep drawing, film
Nb3Sn	18.2	5350,	300	II	Film
MgB2	39	4290,	300	II	Film

Niobium has higher T_c , H_c and enough formability.

Now, niobium is widely used for RF sc cavity production.

Surface resistance of normal conducting Case

Maxwell Equations for conductor ($\epsilon, \mu, \rho = 0$)

$$\nabla \cdot \vec{B} = 0, \nabla \times \vec{E} + \mu \frac{\partial \vec{H}}{\partial t} = 0$$

$$\nabla \cdot \vec{D} = 0, \nabla \times \vec{H} - \epsilon \frac{\partial \vec{E}}{\partial t} - \sigma \vec{E} = 0$$

$$\vec{J} = \sigma \vec{E} \quad (\text{Ohm's Law})$$

$$\vec{E}(\vec{x}, t) = \vec{E}_\ell(\vec{x}, t) + \vec{E}_t(\vec{x}, t),$$

$$\vec{H}(\vec{x}, t) = \vec{H}_\ell(\vec{x}, t) + \vec{H}_t(\vec{x}, t)$$

From Maxwell Equation,

$$\frac{\partial \vec{H}_\ell}{\partial t} = 0, \quad \vec{E}_\ell(\vec{x}, t) = \vec{E}_\ell(0) \cdot e^{-\frac{\sigma t}{\epsilon}}$$

For the transvers,

$$\text{Plane wave : } \vec{E}_t(\vec{x}, t) = \vec{E}_t(0) \cdot \exp(i\vec{k} \cdot \vec{x} - \omega t)$$

$$\vec{H}_t(\vec{x}, t) = \frac{1}{\mu\omega} [\vec{k} \times \vec{E}_t(\vec{x}, t)],$$

$$[k^2 - (\epsilon\mu\omega^2 + i\mu\omega\sigma)] \begin{Bmatrix} \vec{E}_t(\vec{x}, t) \\ \vec{H}_t(\vec{x}, t) \end{Bmatrix} = 0$$

Normal Conducting Case, continued

$$k^2 - (\epsilon\mu\omega^2 + i\mu\omega\sigma) = 0,$$

$$k = \alpha + i\beta,$$

$$\begin{Bmatrix} \alpha \\ \beta \end{Bmatrix} = \sqrt{\epsilon\mu} \cdot \omega \left[\frac{\sqrt{1 + \left(\frac{\sigma}{\omega\epsilon}\right)^2} \pm 1}{2} \right]^{\frac{1}{2}}$$

For good electric conductor

$$\frac{\sigma}{\omega\epsilon} \gg 1$$

$$k \approx (1+i) \sqrt{\frac{\mu\sigma\omega}{2}}$$

$$\delta = \frac{1}{\beta} = \sqrt{\frac{2}{\mu\sigma\omega}} \quad : \text{Skin depth}$$

Surface Impedance for normal conducting case

$$Z \equiv R_s + iX_s \equiv \frac{E_t}{H_t} \Big|_{\text{Surface}} = \frac{\mu\omega}{k}$$

Exercise II.
Get the formula of R_s
for good electric conductor

$$R_s = \sqrt{\frac{\mu\omega}{2\sigma}} = \frac{1}{\sigma} \sqrt{\frac{\mu\sigma\omega}{2}} = \frac{1}{\sigma\delta}$$

$$P_{\text{loss}} = \frac{1}{2} R_s \cdot \int_S H_s^2 dS$$

Surface resistance in superconductor (Two Fluid model)

General equation: $m \frac{\partial \mathbf{v}}{\partial t} = q(\mathbf{E} + \mathbf{v} \times \mathbf{B}) - m\nu \mathbf{v}$

Two-fluid model by Gorter and Casimir in 1933

$$\mathbf{J} = \mathbf{J}_s + \mathbf{J}_n, \quad \mathbf{J}_s = n_s q_s \mathbf{v}, \quad \mathbf{J}_n = n_n q_n \mathbf{v}$$

Maxwell equation: neglecting the Lorentz term, $\mathbf{v} \times \mathbf{B} \ll 1$

$$m_s \frac{\partial \mathbf{v}_s}{\partial t} = q_s \mathbf{E}, \quad m_s = 2m_e, \quad q_s = -2e$$

$$m_e \frac{\partial \mathbf{v}_n}{\partial t} = q_n \mathbf{E} - m_e \nu \mathbf{v}_n, \quad q_n = -e$$

$$\mathbf{E} = \mathbf{E}_0 e^{i\omega t} \Rightarrow \mathbf{J}_s = \frac{n_s q_s^2}{i\omega m_s} \mathbf{E}, \quad \mathbf{J}_n = \frac{n_n q_n^2}{i(\omega - i\nu)m_e} \mathbf{E}$$

$$\mathbf{J} = \left(\frac{n_s q_s^2}{i\omega m_s} + \frac{n_n e^2}{i(\omega - i\nu)m_e} \right) \mathbf{E}$$

$$\nu \gg \omega \Rightarrow \mathbf{J} = \left(\frac{n_n e^2}{\nu m_e} - i \frac{n_s q_s^2}{\omega m_s} \right) \mathbf{E} = \sigma E, \quad \sigma = \sigma_n - i\sigma_s \Rightarrow R_s = \sqrt{\frac{\mu\omega}{2\sigma}}$$

Surface resistance in superconductor

$$\sigma_n = \frac{n_n \cdot e^2 \cdot l}{m \cdot v_F} = \frac{e^2 \cdot l}{m \cdot v_F} \cdot n_s(T=0) \cdot e^{-\frac{\Delta}{k_B T}}$$

Exercise III.
Get this formula.

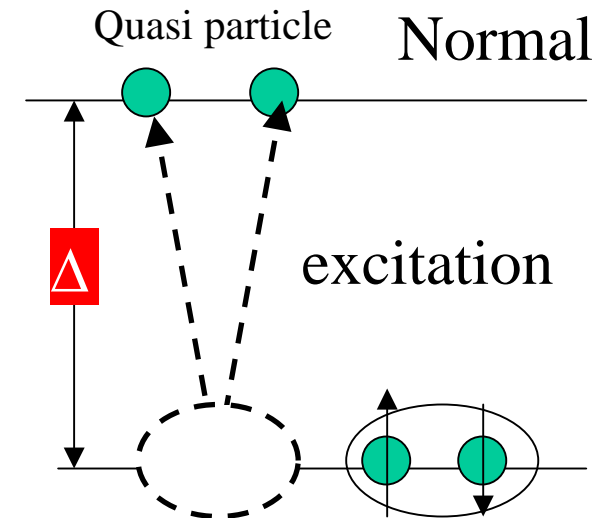
$$R_S = \frac{1}{2} \cdot (2\pi)^2 \cdot \mu^2 \cdot f^2 \cdot \lambda_L^3 \cdot l \cdot \frac{n_s(0)}{m v_F} \cdot e^{-\frac{\Delta}{k_B T}}$$

$$= A \cdot f^2 \cdot e^{-\frac{\Delta}{k_B T}}$$

BCS Theory

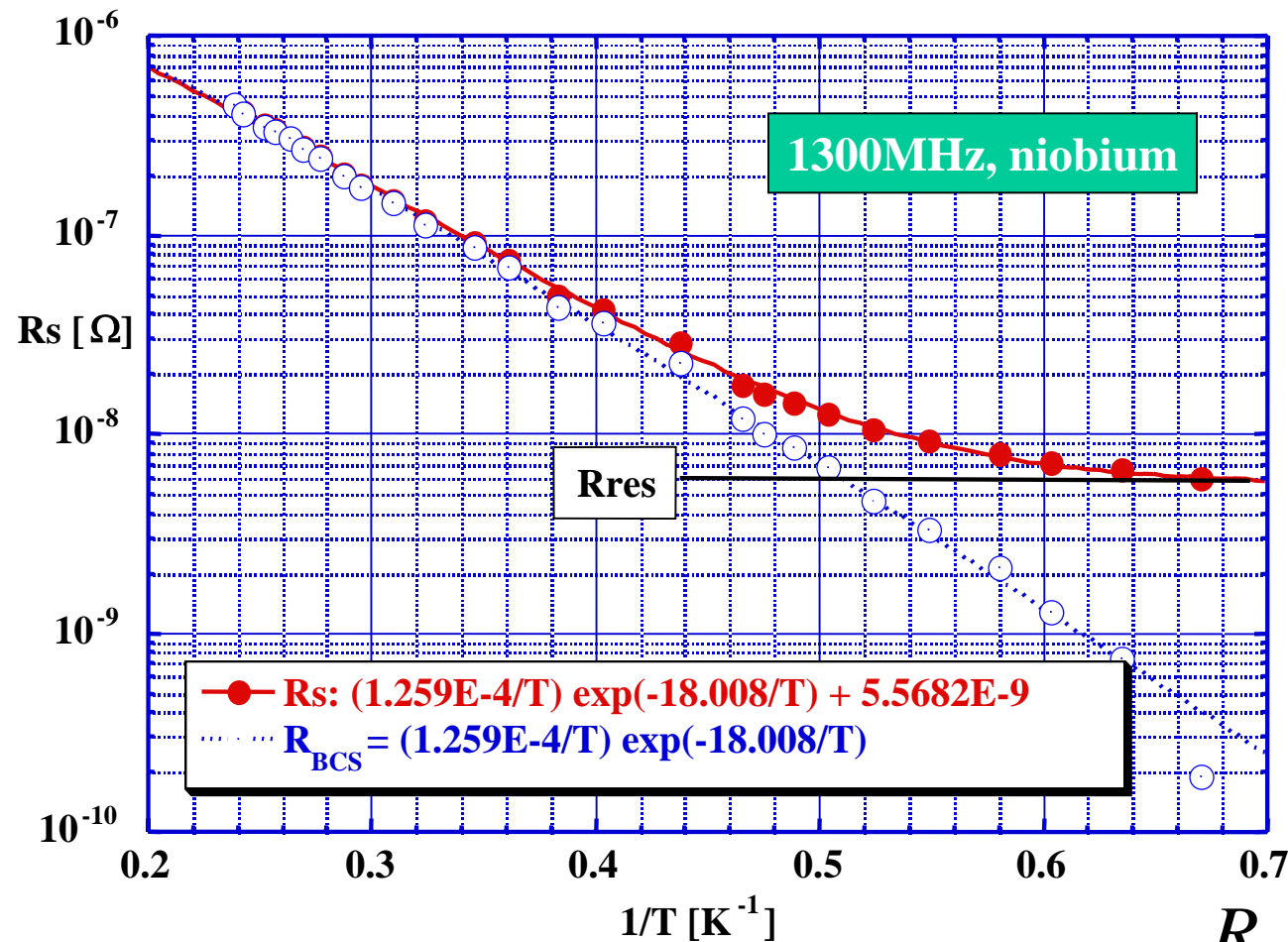
$$R_S^{BCS}(T, \omega) = A(\lambda, \xi, l, T_c) \cdot \frac{f^2}{T} \cdot \exp\left(-\frac{\Delta}{k_B T}\right)$$

At a finite temperature T



Superconducting state

“Very Small” Surface Resistance in SRF Cavity



$$\frac{\Delta}{k_B} = 18.008 \Rightarrow \frac{2\Delta}{k_B T_c} = \frac{2 \cdot 18.008}{9.25} = 3.89$$

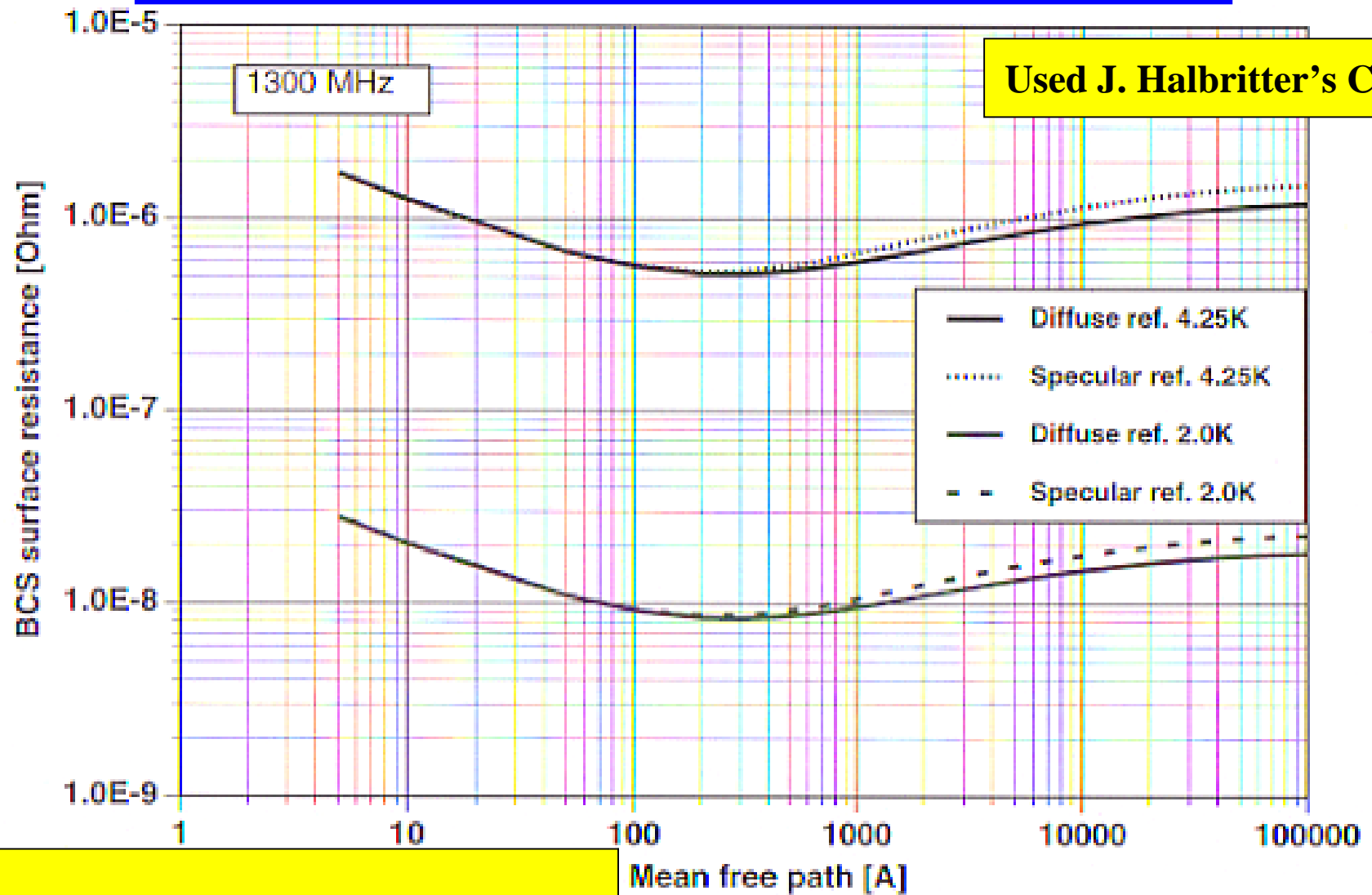
$$\frac{2\Delta}{k_B T_c} = 3.52 \text{ (BCS theory)}$$

Residual surface resistance depends on residual magnetic field, surface contamination, and so on.

$$R_S(T) = R_S^{BCS}(T) + R_{res}$$

$R_{BCS} \sim 8\text{n}\Omega$,
 which is smaller a factor of 10^{-6} than normal conducting!
 The performance strongly depends on the surface!

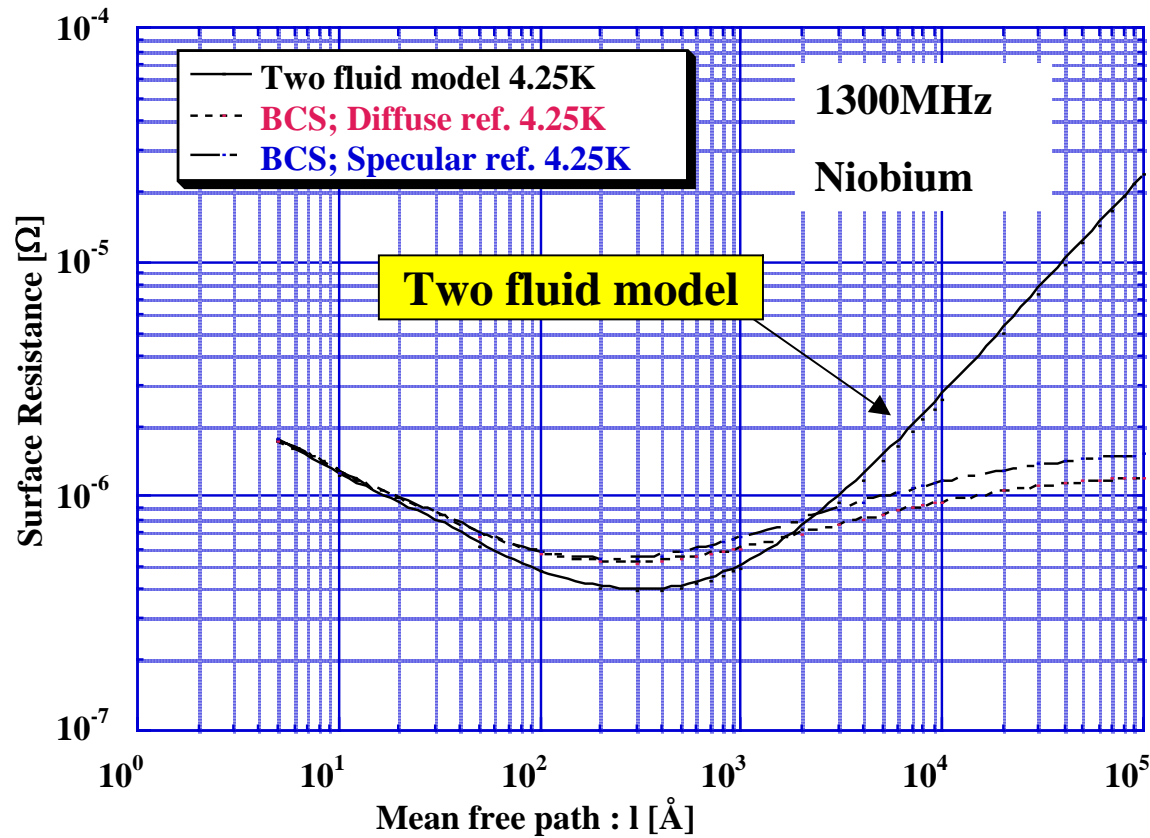
BCS Surface Resistance Calculation for 1.3 GHz niobium cavity at 4.25 and 2K



$$R_{\text{BCS}} \sim 8\text{n}\Omega @ 2\text{K}, 1300\text{MHz}$$

$$\ell(\text{mean free path}) \propto RRR$$

R_s minimum around mean free path $\ell \approx 300 \text{ \AA}$



Strange behavior on mean free path(ℓ)

R_s minimum
@ $\ell \sim 300$

London penetration depth λ : $\lambda(\ell) = \lambda_{\ell=\infty} \cdot \sqrt{1 + \frac{\xi_o}{\ell}}$,

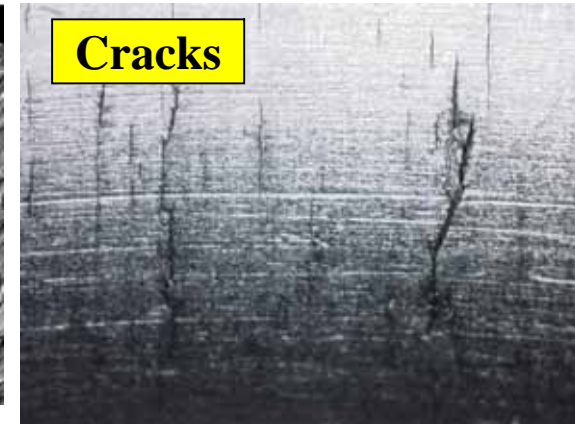
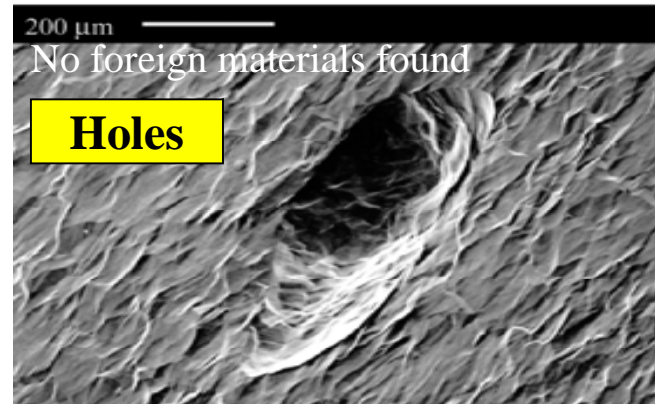
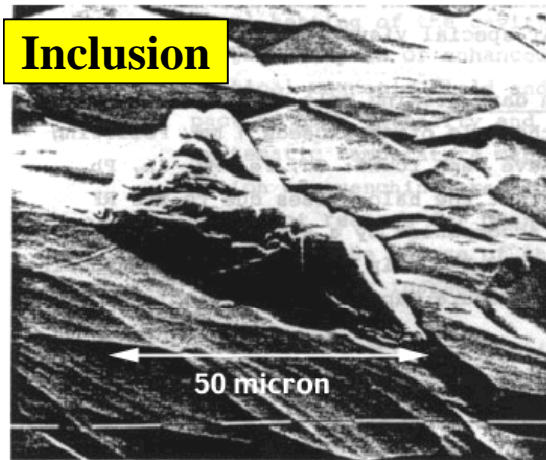
$$R_s(TF \text{ model}) \propto \left(1 + \frac{\xi_o}{\ell}\right)^{\frac{3}{2}} \cdot \ell,$$

$$\ell \ll 1, R_s \rightarrow \frac{\xi_o^{\frac{3}{2}}}{\sqrt{\ell}},$$

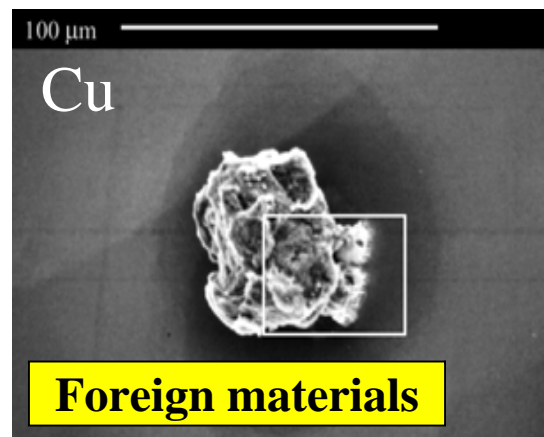
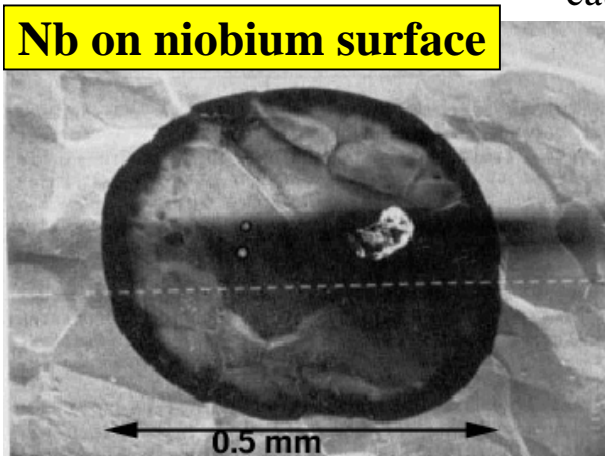
$$\ell \gg 1, R_s \rightarrow \ell$$

1.3 Thermal Conductivity and Residual Resistance Ratio (RRR)

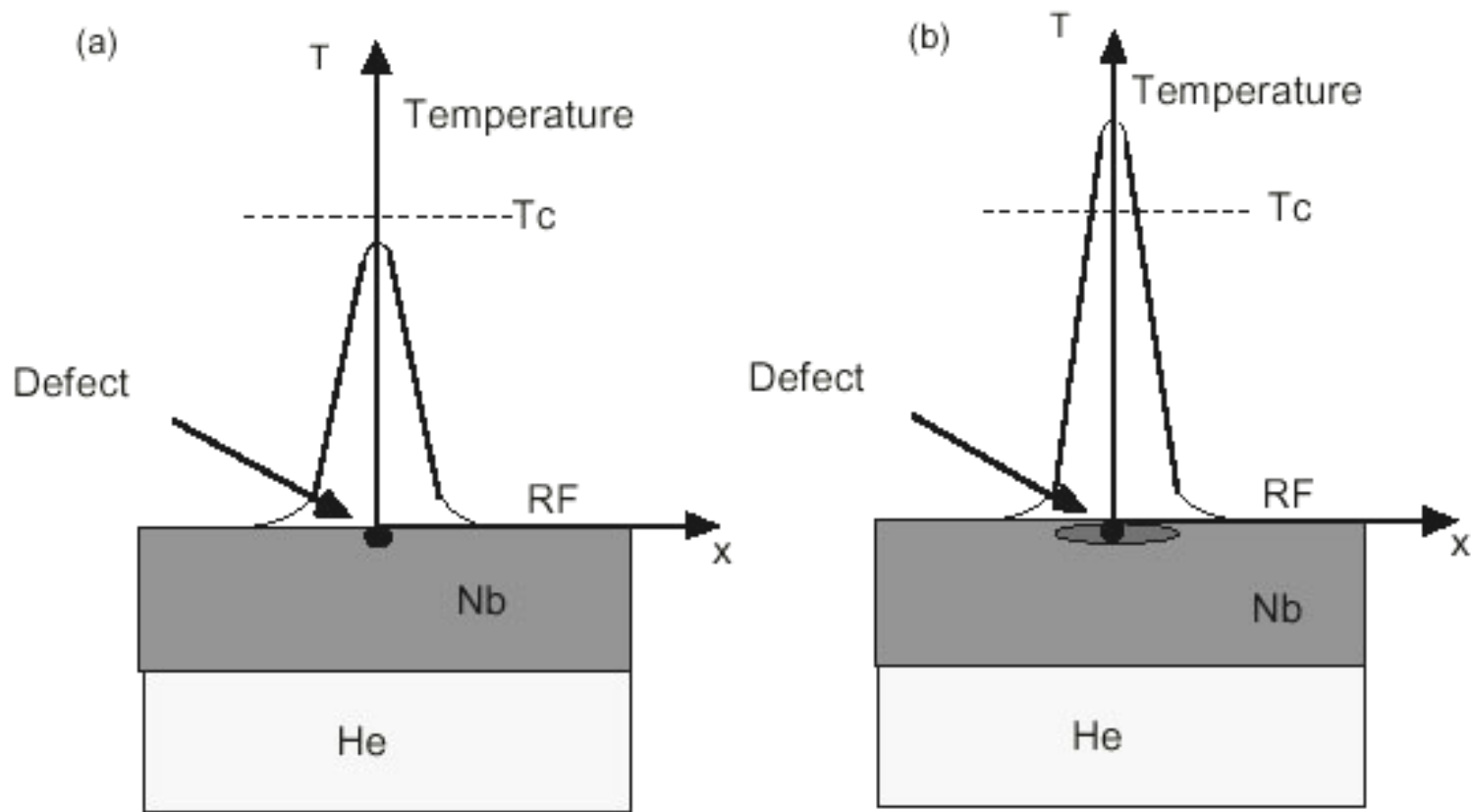
Surface defects on the SRF cavities



Surface defects, holes can also cause TB



Breakdown at the surface defects : “Thermal Instability”



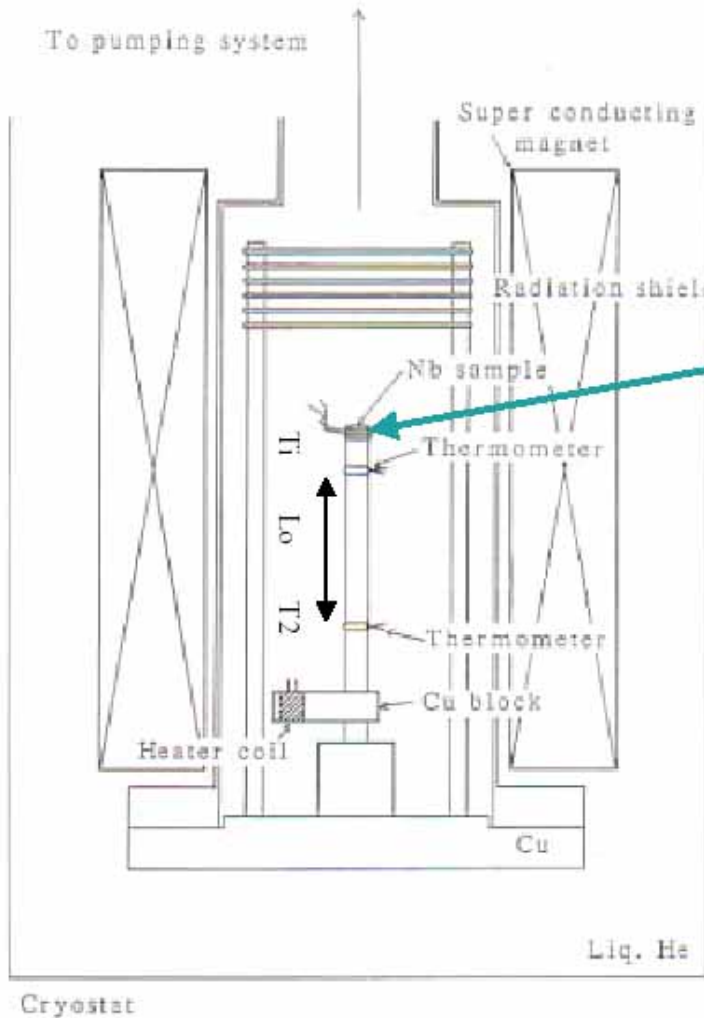
Thermal conductivity

Normal conductor : $\kappa_{en} = \frac{1}{W_{en}} = \left[\frac{\rho}{L_0 T} + a T^2 \right]^{-1}$

$\rho = \frac{\rho_{300K}}{RRR}$ e-impurities scatt.
e-lattices scatt.

Wiedemann-Franz law:

Heater: P[w] $\kappa_e = \frac{\pi^2 n k_B^2 \tau}{3m} \cdot T, \quad \frac{\kappa_e}{\sigma} = \frac{\pi^2}{3} \left(\frac{k_B}{e} \right)^2 \cdot T = L_0 T$

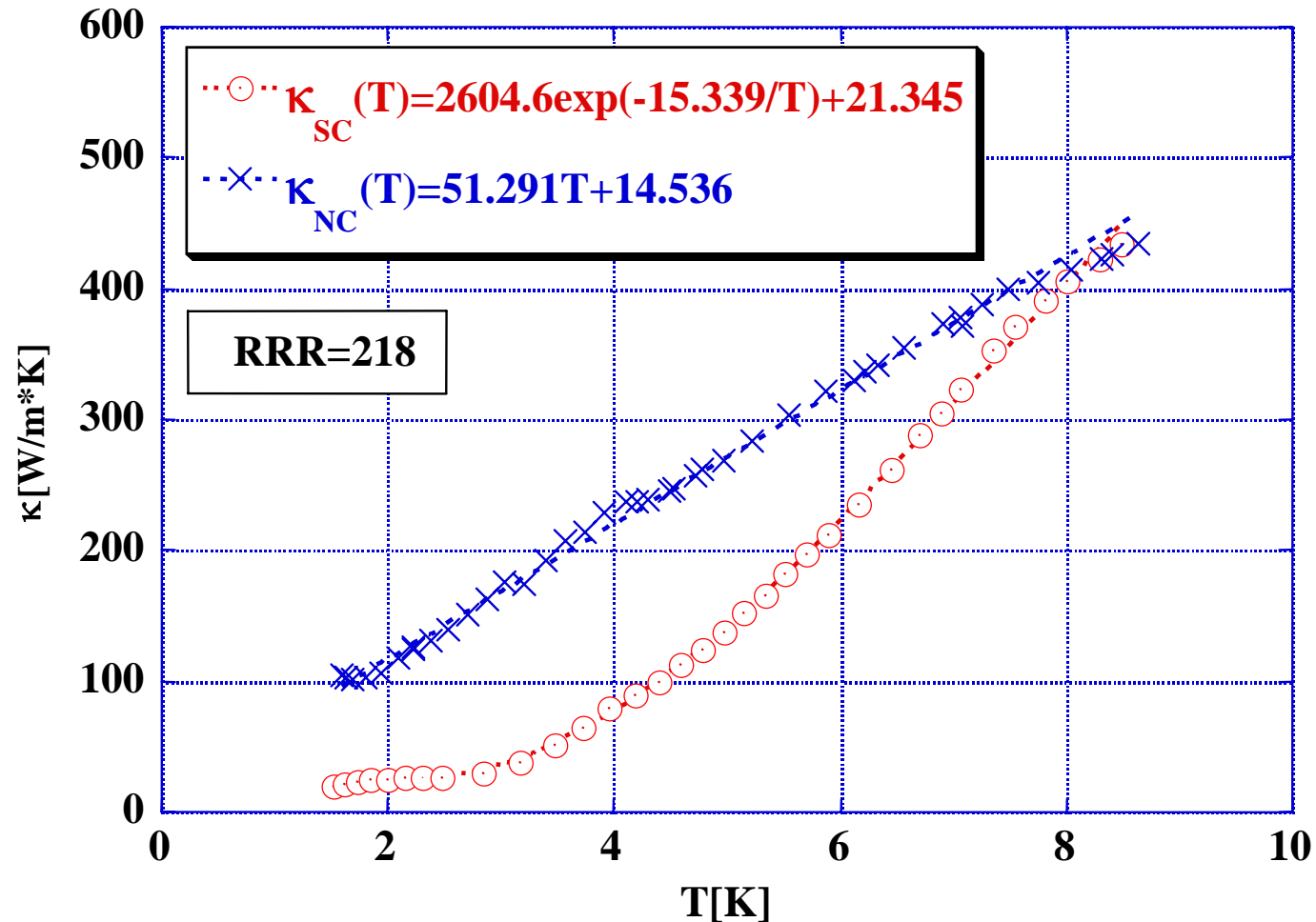


$$P[w] = S(m^2) \cdot \kappa(T) \cdot \frac{T_1(K) - T_2(K)}{L_0(m)}$$

$$T \equiv \frac{T_1 + T_2}{2}, \quad S: \text{ area of cross - section}$$

$$\kappa(T) = \frac{P}{S} \cdot \frac{L_0}{T_1 - T_2} \quad \left[\frac{w}{m \cdot K} \right]$$

Thermal conductivity comparison with NC and SC



$$\frac{\Delta}{k_B} = 15.339$$

↓

$$\frac{2\Delta}{k_B T_c} = \frac{2 \times 15.339}{k_B 9.25}$$

$$2\Delta = 3.317 k_B T_c$$

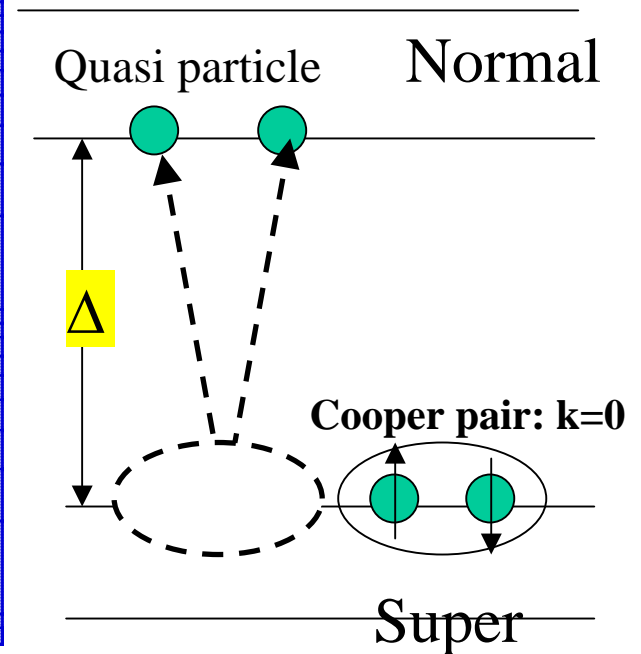
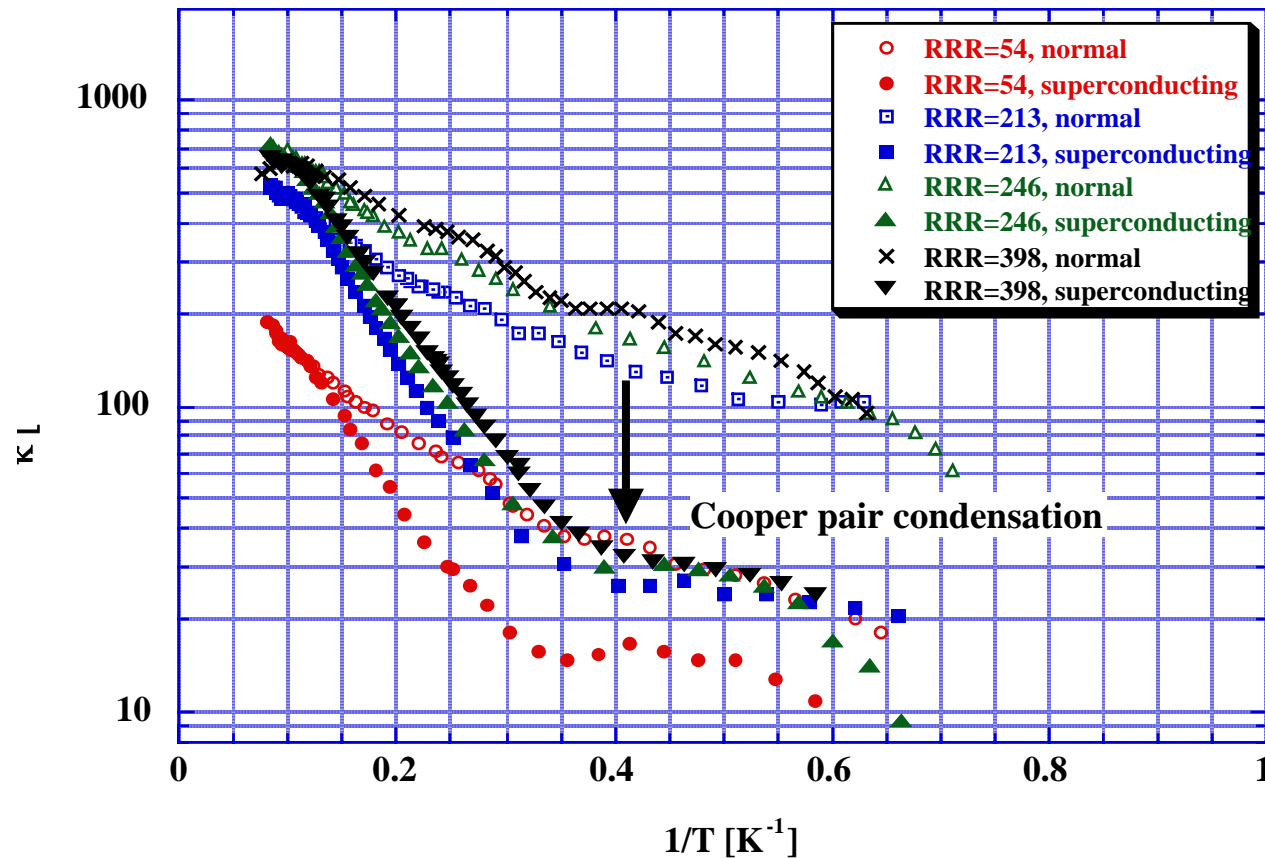
BCS theory

$$2\Delta = 3.52 k_B T_c$$

Thermal conductivity of Nb material at low temperature

Boltzmann statistics : Existing probability
at energy Δ , and Temp. T

$$\exp\left(-\frac{\Delta}{k_B \cdot T}\right)$$



Calculation of thermal conductivity based on Quantum mechanics

$$\kappa_s(T) = R(y) \cdot \left[\frac{\rho_{295K}}{L \cdot RRR \cdot T} + a \cdot T^2 \right]^{-1} + \left[\frac{1}{D \cdot \exp(y) \cdot T^2} + \frac{1}{BlT^3} \right]^{-1}$$

\swarrow e-impurities scatt. \swarrow e-phonons scatt. \swarrow lattice-phonons scatt. \swarrow lattice-grain boundaries scatt.

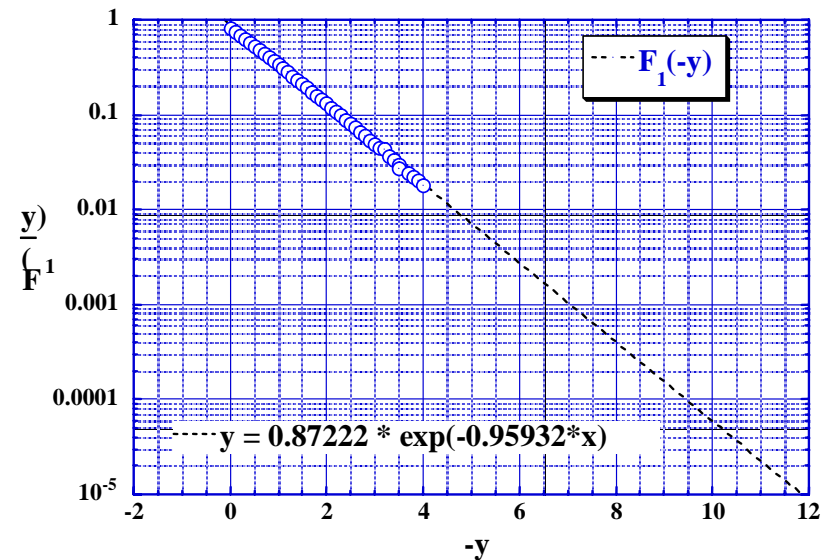
$$L = 2.05E-8, RRR = 200, \rho_{295K} = 14.5E-8 \Omega m, a = 7.52E-7$$

$$-y = \alpha \cdot \frac{T_c}{T}, \alpha = 1.53, T_c = 9.25K, T \leq 0.6 \cdot T_c$$

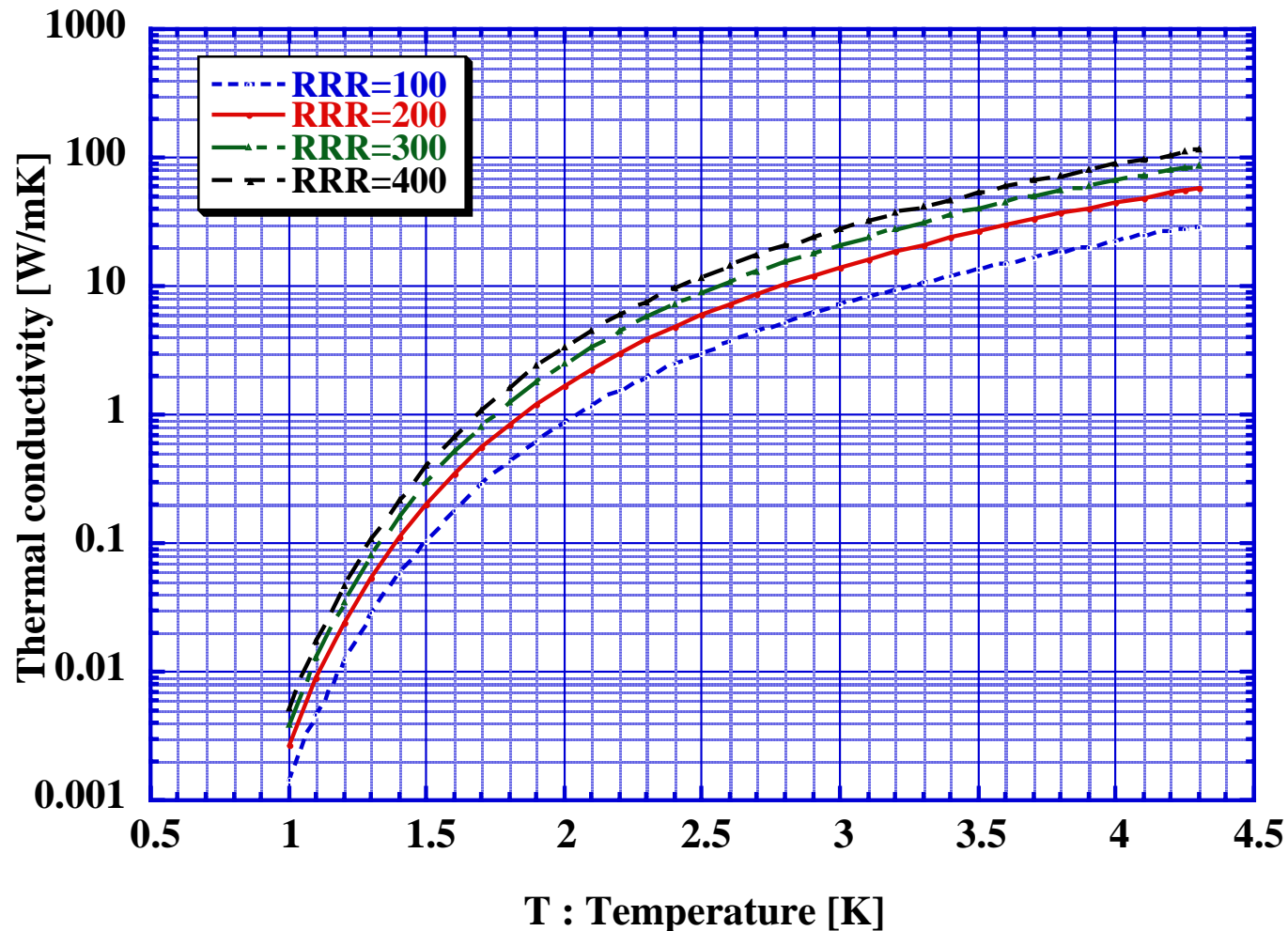
$$D = 4.27E-3, B = 4.34E3, l = 50\mu m$$

$$R(y) = \frac{\kappa_{es}}{\kappa_{en}} = \frac{2F_1(-y) + 2y \ln(1 + e^{-y}) + \frac{y^2}{(1 + e^y)}}{2F_1(0)},$$

$$F_n(-y) = \int_0^\infty \frac{z^n}{1 + e^{z+y}} dz$$

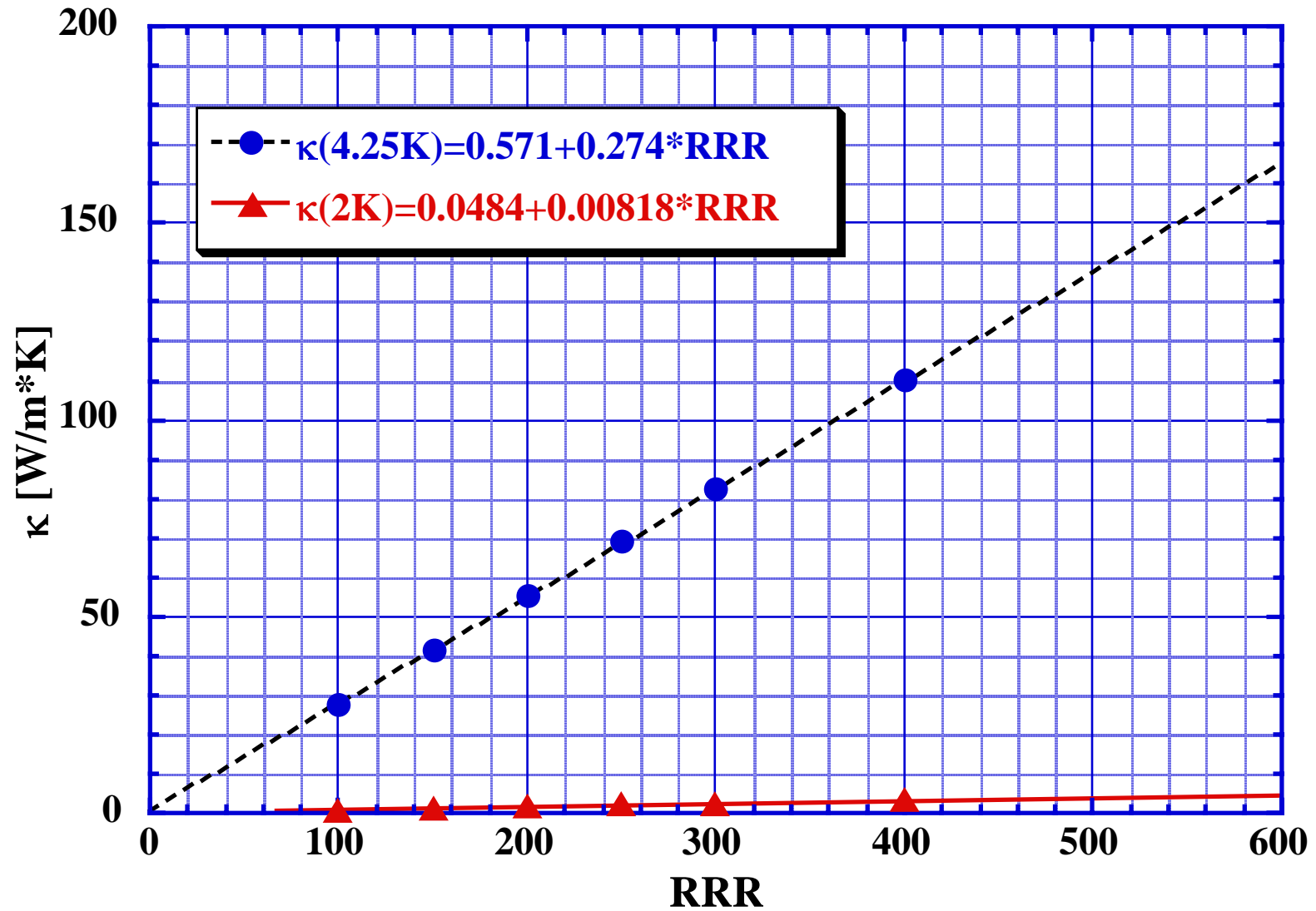


Calculated $\kappa_{sc}(T)$



Thermal conductivity of niobium in superconductivity @ 2K is 1/15 that of stainless at R.T. (15W/(m•K)) and 1/6800 of pure cooper at 4.2K

Linear relationship between κ_{sc} (2K, 4.25K) and RRR

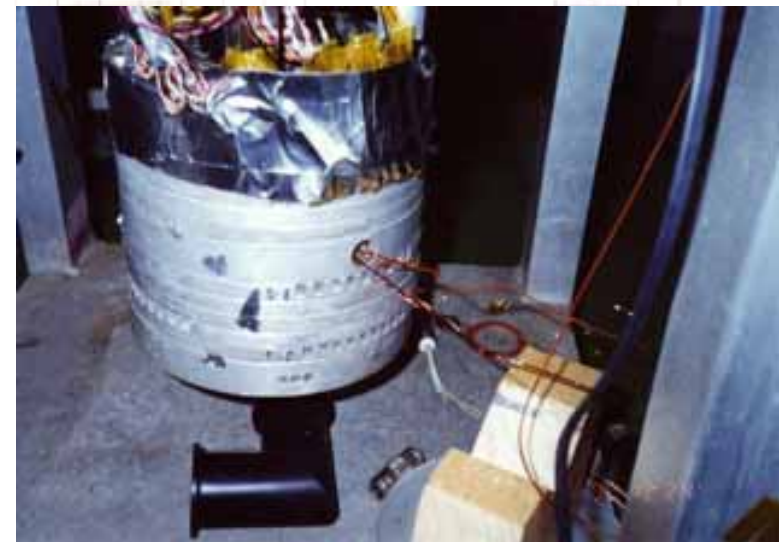
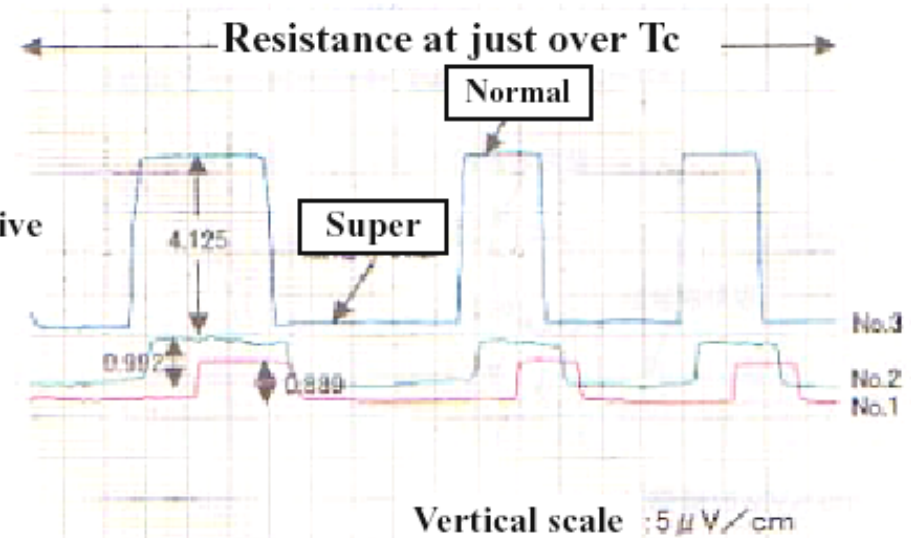
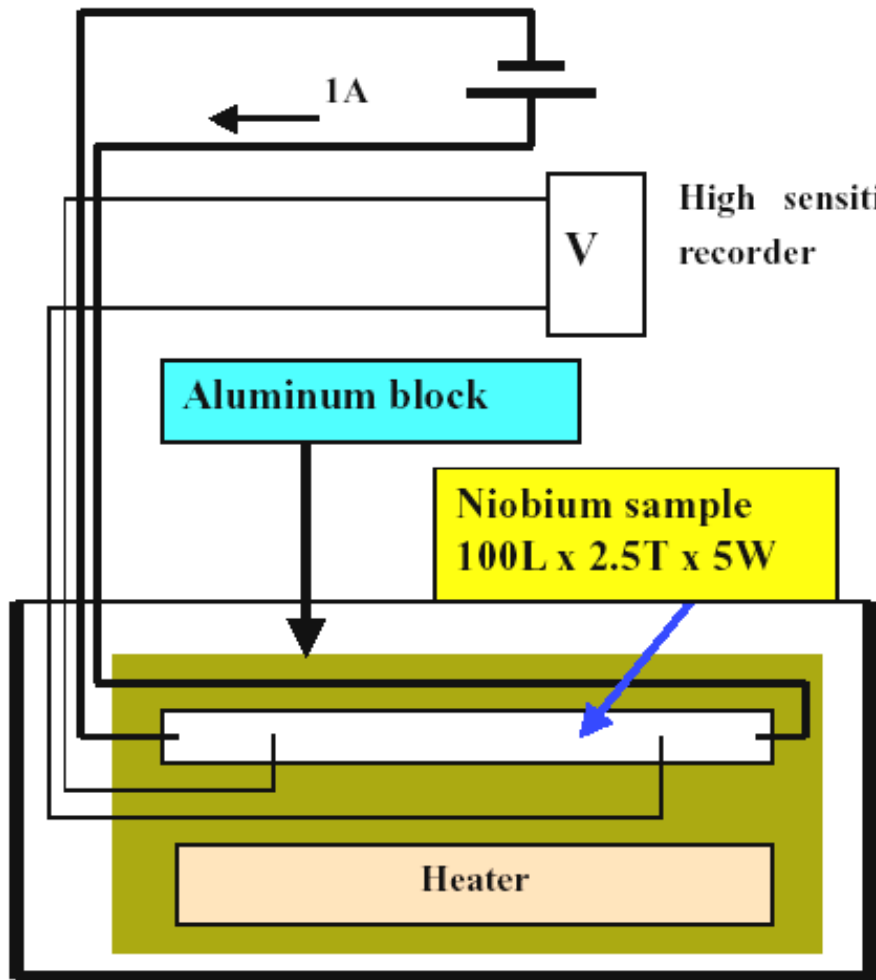


RRR measurement

Very simple measurement!!

RRR is linearly proportional to thermal conductivity.

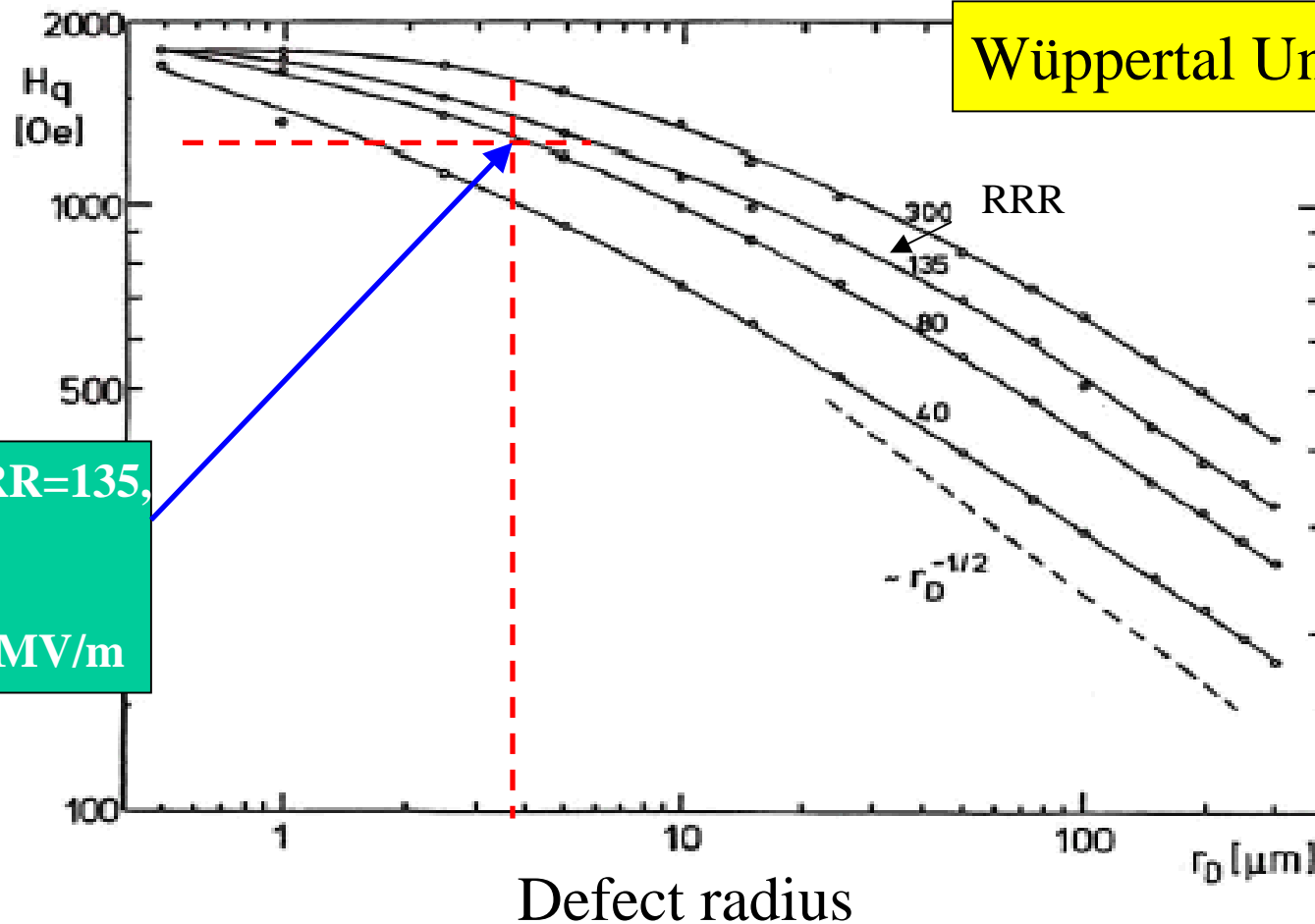
$$RRR \equiv \frac{R_{300K}}{R_{9.5K}}$$



High RRR Material to Suppress the Thermal Instability

$$\text{Quench Field : } H_q = \sqrt{\frac{4\kappa(T_c - T_b)}{r_D \cdot R_s(T_b)}} \propto RRR^{\frac{3}{4}} \cdot \sqrt{\frac{(T_c - T_b)}{r_D \cdot R_s(300K)}}$$

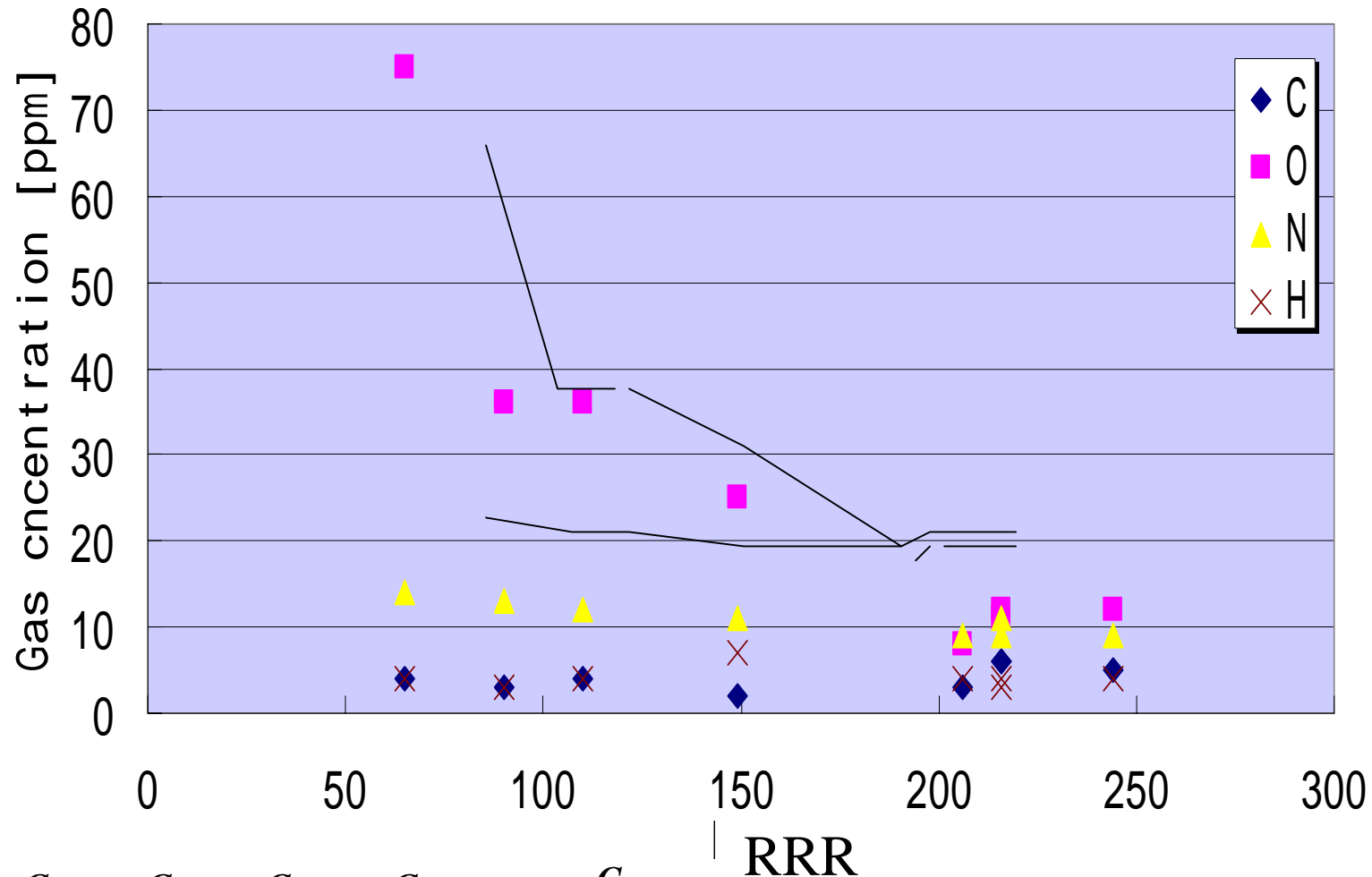
Wuppertal University



The case : RRR=135,
and $r_D=3\mu\text{m}$
 $H_q \sim 1500\text{Oe}$
 $E_{\text{acc,max}} \sim 34\text{MV/m}$

One has to control the defects smaller than 1 μm radius. Use the material with RRR >200.

Impurities in Nb Material



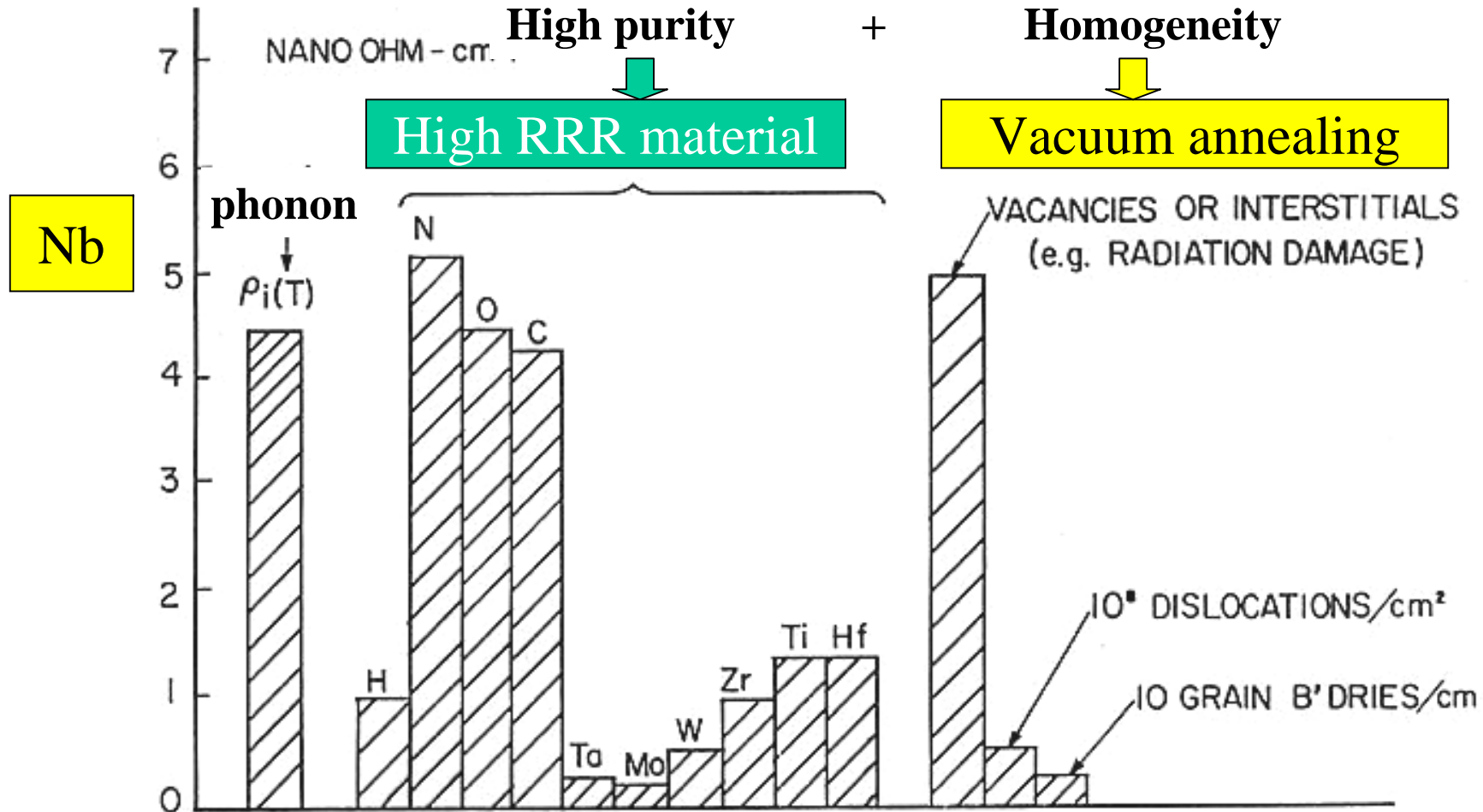
$$\frac{1}{RRR} = \frac{C_H}{1500} + \frac{C_C}{4100} + \frac{C_N}{3900} + \frac{C_O}{5000} + \dots + \frac{C_{Ta}}{550000} + \dots$$

Example : $C_H = 1\text{ppm}$, $C_C = 5\text{ppm}$, $C_N = 5\text{ppm}$, $C_O = 7\text{ppm}$, $Ta = 400\text{ppm}$ (purity: 99.9582%)

$$\frac{1}{RRR} = \frac{1}{1500} + \frac{5}{4100} + \frac{5}{3900} + \frac{7}{5000} + \frac{400}{550000}, \quad RRR = 188.8$$

Theoretical limit : $Ta = 100\text{ppm}$, $RRR = 5500$

Scattering mechanism limits both thermal conductivity and electric conductivity



$$R = \text{e-phonon scat.} + \text{e-impurity scat.} + \text{e-inhomogeneity scat.} + \dots$$

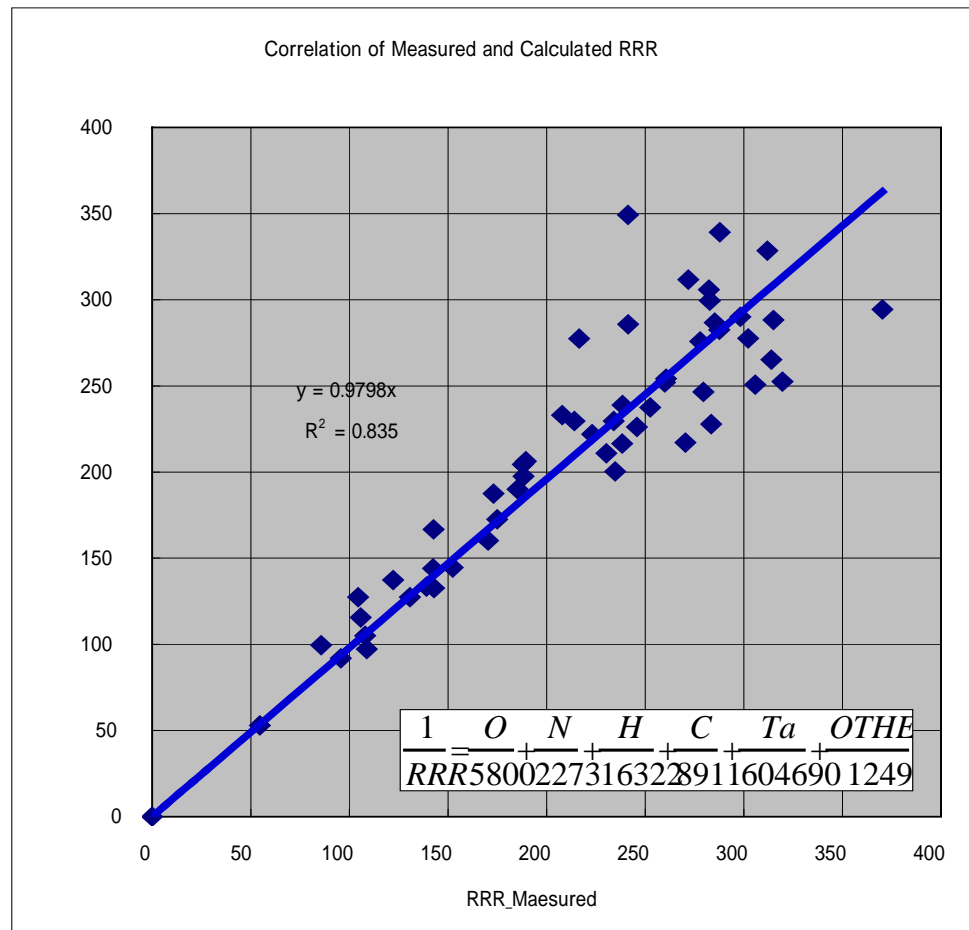
$$\frac{1}{\kappa} = \text{e-phonon scat.} + \text{e-impurity scat.} + \text{e-inhomogeneity scat.} + \dots$$

RRR vs. Impurities

Umezawa's calculation (Tokyo Denkai).

$$\frac{1}{RRR} = \frac{O}{5800} + \frac{N}{2273} + \frac{H}{16322} + \frac{C}{8911} + \frac{Ta}{604690} + \frac{1}{1249}$$

$$RRR \equiv \frac{R(300K)}{R(9.5K)}$$



History of RRR improvement in Tokyo Denkai

